ISL62883, ISL62883B

intersil

Multiphase PWM Regulator for IMVP-6.5[™] Mobile CPUs

ISL62883, ISL62883B

The ISL62883 is a multiphase PWM buck regulator for miroprocessor core power supply. The multiphase buck converter uses interleaved phase to reduce the total output voltage ripple with each phase carrying a portion of the total load current, providing better system performance, superior thermal management, lower component cost, reduced power dissipation, and smaller implementation area. The ISL62883 uses two integrated gate drivers and an external gate driver to provide a complete solution. The PWM modulator is based on Intersil's Robust Ripple Regulator (R³) technology[™]. Compared with traditional modulators, the $R^{3_{TM}}$ modulator commands variable switching frequency during load transients, achieving faster transient response. With the same modulator, the switching frequency is reduced at light load, increasing the regulator efficiency.

The ISL62883 is fully compliant with IMVP-6.5™ specifications. It responds to PSI# and DPRSLPVR signals by adding or dropping PWM3 and Phase 2 respectively, adjusting overcurrent protection threshold accordingly, and entering/exiting diode emulation mode. It reports the regulator output current through the IMON pin. It senses the current by using either discrete resistor or inductor DCR whose variation over temperature can be thermally compensated by a single NTC thermistor. It uses differential remote voltage sensing to accurately regulate the processor die voltage. The adaptive body diode conduction time reduction function minimizes the body diode conduction loss in diode emulation mode. User-selectable overshoot reduction function offers an option to aggressively reduce the output capacitors as well as the option to disable it for users concerned about increased system thermal stress. In 2-Phase configuration, the ISL62883 offers the FB2 function to optimize 1-Phase performance.

The ISL62883B has the same functions as the ISL62883, but comes in a different package.

Features

- Precision Multiphase Core Voltage Regulation
 - 0.5% System Accuracy Over-Temperature
 - Enhanced Load Line Accuracy
- Microprocessor Voltage Identification Input
 - 7-Bit VID Input, 0.300V to 1.500V in 12.5mV Steps
 - Supports VID Changes On-The-Fly
- Supports Multiple Current Sensing Methods
 - Lossless Inductor DCR Current Sensing
 - Precision Resistor Current Sensing
- Supports PSI# and DPRSLPVR modes
- Superior Noise Immunity and Transient Response
- Current Monitor and Thermal Monitor
- Differential Remote Voltage Sensing
- High Efficiency Across Entire Load Range
- Programmable 1-, 2- or 3-Phase Operation
- Two Integrated Gate Drivers
- Excellent Dynamic Current Balance Between Phases
- FB2 Function in 2-Phase Configuration to Optimize 1-Phase Performance
- Adaptive Body Diode Conduction Time Reduction
- User-selectable Overshoot Reduction Function
- Small Footprint 40 Ld 5x5 or 48 Ld 6x6 TQFN Package
- Pb-Free (RoHS Compliant)

Applications

Notebook Computers

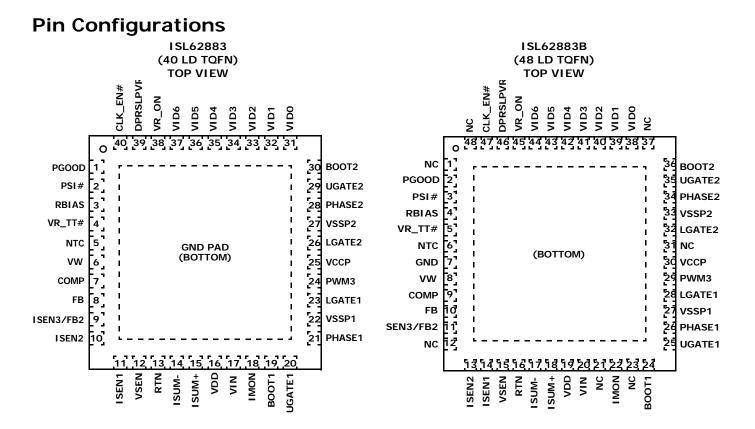
PART NUMBER (Notes 1, 2, 3)	PART MARKING	TEMP. RANGE (°C)	PACKAGE (Pb-Free)	PKG. DWG. #
ISL62883HRTZ	62883 HRTZ	-10 to +100	40 Ld 5x5 TQFN	L40.5x5
ISL62883IRTZ	62883 IRTZ	-40 to +100	40 Ld 5x5 TQFN	L40.5x5
ISL62883BHRTZ	62883 BHRTZ	-10 to +100	48 Ld 6x6 TQFN	L48.6x6

NOTES:

1. Add "-T*" suffix for tape and reel. Please refer to TB347 for details on reel specifications.

2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

3. For Moisture Sensitivity Level (MSL), please see device information page for <u>ISL62883</u>, <u>ISL62883B</u>. For more information on MSL please see techbrief <u>TB363</u>.



Pin Function Description

GND

Signal common of the IC. Unless otherwise stated, signals are referenced to the GND pin.

PGOOD

Power-Good open-drain output indicating when the regulator is able to supply regulated voltage. Pull up externally with a 680Ω resistor to VCCP or $1.9k\Omega$ to 3.3V.

PSI#

Low load current indicator input. When asserted low, indicates a reduced load-current condition. For ISL62883, when PSI# is asserted low, PWM3 will be disabled.

RBIAS

147k Resistor to GND sets internal current reference.

VR_TT#

Thermal overload output indicator.

NTC

Thermistor input to VR_TT# circuit.

vw

A resistor from this pin to COMP programs the switching frequency ($8k\Omega$ gives approximately 300kHz).

COMP

This pin is the output of the error amplifier. Also, a resistor across this pin and GND adjusts the overcurrent threshold.

FB

This pin is the inverting input of the error amplifier.

ISEN3/FB2

When the ISL62883 is configured in 3-phase mode, this pin is ISEN3. ISEN3 is the individual current sensing for phase 3. When the ISL62883 is configured in 2-phase mode, this pin is FB2. There is a switch between the FB2 pin and the FB pin. The switch is on in 2-phase mode and is off in 1-phase mode. The components connecting to FB2 are used to adjust the compensation in 1-phase mode to achieve optimum performance.

ISEN2

Individual current sensing for Phase-2. When ISEN2 is pulled to 5V VDD, the controller will disable Phase-2 and allow other phases to operate.

3

ISEN1

Individual current sensing for phase 1.

VSEN

Remote core voltage sense input. Connect to microprocessor die.

RTN

Remote voltage sensing return. Connect to ground at microprocessor die.

ISUM- and ISUM+

Droop current sense input.

VDD

5V bias power.

VIN

Battery supply voltage, used for feed-forward.

IMON

An analog output. IMON outputs a current proportional to the regulator output current.

BOOT1

Connect an MLCC capacitor across the BOOT1 and the PHASE1 pins. The boot capacitor is charged through an internal boot diode connected from the VCCP pin to the BOOT1 pin, each time the PHASE1 pin drops below VCCP minus the voltage dropped across the internal boot diode.

UGATE1

Output of the Phase-1 high-side MOSFET gate driver. Connect the UGATE1 pin to the gate of the Phase-1 high-side MOSFET.

PHASE1

Current return path for the Phase-1 high-side MOSFET gate driver. Connect the PHASE1 pin to the node consisting of the high-side MOSFET source, the low-side MOSFET drain, and the output inductor of phase 1.

VSSP1

Current return path for the Phase-1 low-side MOSFET gate driver. Connect the VSSP1 pin to the source of the Phase-1 low-side MOSFET through a low impedance path, preferably in parallel with the trace connecting the LGATE1 pin to the gate of the Phase-1 low-side MOSFET.

LGATE1

Output of the Phase-1 low-side MOSFET gate driver. Connect the LGATE1 pin to the gate of the Phase-1 low-side MOSFET.

PWM3

PWM output for Channel 3. When PWM3 is pulled to 5V VDD, the controller will disable Phase-3 and allow other phases to operate.

VCCP

Input voltage bias for the internal gate drivers. Connect +5V to the VCCP pin. Decouple with at least 1 μ F of an MLCC capacitor to VSSP1 and VSSP2 pins respectively.

LGATE2

Output of the Phase-2 low-side MOSFET gate driver. Connect the LGATE2 pin to the gate of the Phase-2 low-side MOSFET.

VSSP2

Current return path for the Phase-2 converter low-side MOSFET gate driver. Connect the VSSP2 pin to the source of the Phase-2 low-side MOSFET through a low impedance path, preferably in parallel with the trace connecting the LGATE2 pin to the gate of the Phase-2 low-side MOSFET.

PHASE2

Current return path for the Phase-2 high-side MOSFET gate driver. Connect the PHASE2 pin to the node consisting of the high-side MOSFET source, the low-side MOSFET drain, and the output inductor of phase 2.

UGATE2

Output of the Phase-2 high-side MOSFET gate driver. Connect the UGATE2 pin to the gate of the Phase-2 high-side MOSFET.

BOOT2

Connect an MLCC capacitor across the BOOT2 and the PHASE2 pins. The boot capacitor is charged through an internal boot diode connected from the VCCP pin to the BOOT2 pin, each time the PHASE2 pin drops below VCCP minus the voltage dropped across the internal boot diode.

VIDO, VID1, VID2, VID3, VID4, VID5, VID6

VID input with VID0 = LSB and VID6 = MSB.

VR_ON

Voltage regulator enable input. A high level logic signal on this pin enables the regulator.

DPRSLPVR

Deeper sleep enable signal. A high level logic signal on this pin indicates that the microprocessor is in deeper sleep mode.

CLK_EN#

Open drain output to enable system PLL clock. It goes low 13 switching cycles after V_{core} is within 10% of $V_{boot}.$

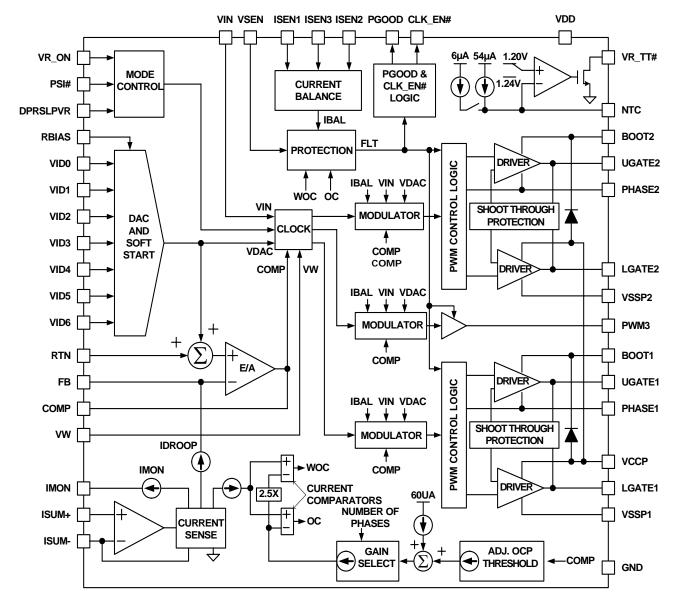
NC

No Connect.

BOTTOM (on ISL62883B)

The bottom pad of ISL62883B is electrically connected to the GND pin inside the IC.

Block Diagram



Absolute Maximum Ratings

Supply Voltage, VDD
Battery Voltage, VIN+28V
Boot Voltage (BOOT)
Boot to Phase Voltage (BOOT-PHASE)0.3V to +7V(DC)
0.3V to +9V(<10ns)
Phase Voltage (PHASE)7V (<20ns Pulse Width, 10µJ)
UGATE Voltage (UGATE) PHASE - 0.3V (DC) to BOOT
PHASE-5V (<20ns Pulse Width, 10µJ) to BOOT
LGATE Voltage (LGATE)0.3V (DC) to VDD + 0.3V
All Other Pins0.3V to (VDD +0.3V)
Open Drain Outputs, PGOOD, VR_TT#,
CLK_EN#

Thermal Information

Thermal Resistance (Typical)	θ _{JA} (°C/W)	θ _{JC} (°C/W)
40 Ld TQFN Package (Notes 4, 5).	. 32	3
48 Ld TQFN Package (Notes 4, 5).	. 29	2
Maximum Junction Temperature		+150°C
Maximum Storage Temperature Rang	је <mark>-6</mark> 5°	°C to +150°C
Pb-Free Reflow Profile	S	ee link below
http://www.intersil.com/pbfree/Pb	-FreeReflow.	<u>asp</u>

Recommended Operating Conditions

Supply Voltage, VDD
Ambient Temperature
ISL62883HRTZ, ISL62883BHRTZ10°C to +100°C
ISL62883IRTZ
Junction Temperature
ISL62883HRTZ, ISL62883BHRTZ10°C to +125°C
ISL62883IRTZ

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

- 4. θ_{JA} is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.
- 5. For θ_{JC} , the "case temp" location is the center of the exposed metal pad on the package underside.

Electrical Specification		ditions: VDD = 5V, $T_A = -40^{\circ}C$ to $+100^{\circ}C$ ce limits apply over the operating tem $10^{\circ}C$.			nless othe	rwise
PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 6)	түр	MAX (Note 6)	UNITS
INPUT POWER SUPPLY		•			-	-
+5V Supply Current	I _{VDD}	$VR_ON = 1V$		4	4.6	mA
		VR_ON = OV			1	μA
Battery Supply Current	I _{VIN}	VR_ON = OV			1	μA
V _{IN} Input Resistance	R _{VIN}	VR_ON = 1V		900		kΩ
Power-On-Reset Threshold	PORr	V _{DD} rising		4.35	4.5	V
	PORf	V _{DD} falling	4.00	4.15		V
SYSTEM AND REFERENCES						
System Accuracy	HRTZ %Error	No load; closed loop, active mode range VID = 0.75V to 1.50V,	-0.5		+0.5	%
	(V _{CC_CORE})	VID = 0.5V to 0.7375V	-8		+8	mV
		VID = 0.3V to 0.4875V	-15		+15	mV
	IRTZ %Error	No load; closed loop, active mode range VID = 0.75V to 1.50V,	-0.8		+0.8	%
	(V _{CC_CORE})	VID = 0.5V to 0.7375V	-10		+10	mV
		VID = 0.3V to 0.4875V	-18		+18	mV
V _{BOOT}			1.0945	1.100	1.1055	V
Maximum Output Voltage	V _{CC_CORE(max)}	VID = [0000000]		1.500		V
Minimum Output Voltage	V _{CC_CORE} (min)	VID = [1100000]		0.300		V
R _{BIAS} Voltage		$R_{BIAS} = 147 k\Omega$	1.45	1.47	1.49	V

ISL62883, ISL62883B

Electrical Specifications

Operating Conditions: VDD = 5V, T_A = -40°C to +100°C, f_{SW} = 300kHz, unless otherwise noted. Boldface limits apply over the operating temperature range, -40°C to +100°C. (Continued)

PARAMETER SYMBOL TEST CONDITIONS		MIN (Note 6)	түр	MAX (Note 6)	UNITS	
CHANNEL FREQUENCY						
Nominal Channel Frequency	^f SW(nom)	om) Rfset = $7k\Omega$, 3 channel operation, V _{COMP} = 1V		300	315	kHz
Adjustment Range			200		500	kHz
AMPLIFIERS	·				•	
Current-Sense Amplifier Input Offset		I _{FB} = 0A	-0.15		+0.15	mV
Error Amp DC Gain	A _{v0}			90		dB
Error Amp Gain-Bandwidth Product	GBW	C _L = 20pF		18		MHz
ISEN						
Imbalance Voltage		Maximum of ISENs - Minimum of ISENs			1	mV
Input Bias Current				20		nA
POWER GOOD AND PROTECTI	ON MONITOR	'S	1	r		
PGOOD Low Voltage	V _{OL}	$I_{PGOOD} = 4mA$		0.26	0.4	V
PGOOD Leakage Current	I _{ОН}	PGOOD = 3.3V	-1		1	μA
PGOOD Delay	tpgd	CLK_EN# LOW to PGOOD HIGH	6.3	7.6	8.9	ms
GATE DRIVER			1	r		
UGATE Pull-Up Resistance	R _{UGPU}	200mA Source Current		1.0	1.5	Ω
UGATE Source Current	IUGSRC	UGATE - PHASE = 2.5V		2.0		Α
UGATE Sink Resistance	R _{UGPD}	250mA Sink Current		1.0	1.5	Ω
UGATE Sink Current	I _{UGSNK}	UGATE - PHASE = 2.5V		2.0		А
LGATE Pull-Up Resistance	R _{LGPU}	250mA Source Current		1.0	1.5	Ω
LGATE Source Current	ILGSRC	LGATE - VSSP = 2.5V		2.0		А
LGATE Sink Resistance	R _{LGPD}	250mA Sink Current		0.5	0.9	Ω
LGATE Sink Current	I _{LGSNK}	LGATE - VSSP = 2.5V		4.0		Α
UGATE to LGATE Deadtime	tUGFLGR	UGATE falling to LGATE rising, no load		23		ns
LGATE to UGATE Deadtime	t _{LGFUGR}	LGATE falling to UGATE rising, no load		28		ns
BOOTSTRAP DIODE						
Forward Voltage	V _F	$PVCC = 5V, I_F = 2mA$		0.58		V
Reverse Leakage	I _R	$V_{R} = 25V$		0.2		μΑ
PROTECTION						
Overvoltage Threshold	OV _H	VSEN rising above setpoint for >1ms	150	195	240	mV
Severe Overvoltage Threshold	OV _{HS}	VSEN rising for >2µs	1.525	1.55	1.575	V
OC Threshold Offset at		3-phase configuration, ISUM- pin current	28.4	30.3	32.2	μA
Rcomp = Open Circuit		2-phase configuration, ISUM- pin current	18.3	20.2	22.1	μA
		1-phase configuration, ISUM- pin current	8.2	10.1	12.0	μA
Current Imbalance Threshold		One ISEN above another ISEN for >1.2ms		9		mV
Undervoltage Threshold	UVf	VSEN falling below setpoint for >1.2ms	-355	-295	-235	mV

ISL62883, ISL62883B

Electrical Specifications

S Operating Conditions: VDD = 5V, T_A = -40°C to +100°C, f_{SW} = 300kHz, unless otherwise noted. Boldface limits apply over the operating temperature range, -40°C to +100°C. (Continued)

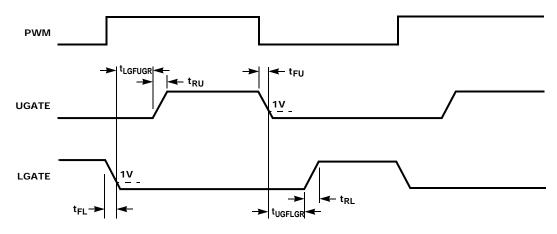
PARAMETER	SYMBOL	TEST CONDITIONS	MIN (Note 6)	ТҮР	MAX (Note 6)	UNITS
LOGIC THRESHOLDS						
VR_ON Input Low	V _{IL(1.0V)}				0.3	V
VR_ON Input High	HRTZ		0.7			V
	V _{IH(1.0V})					
	IRTZ V _{IH(1.0V)}		0.75			V
VID0-VID6, PSI#, and	V _{IL(1.0V)}				0.3	V
DPRSLPVR Input Low	*IL(1.0V)				0.5	v
VID0-VID6, PSI#, and DPRSLPVR Input High	V _{IH(1.0V)}		0.7			V
PWM	L		ŀ	1		
PWM3 Output Low	V _{OL(5.0V)}	Sinking 5mA			1.0	V
PWM3 Output High	V _{OH(5.0V)}	Sourcing 5mA	3.5			V
PWM Tri-State Leakage		PWM = 2.5V		2		μA
THERMAL MONITOR	L		ŀ	1		
NTC Source Current		NTC = 1.3V	53	60	67	μA
Over-Temperature Threshold		V (NTC) falling	1.18	1.2	1.22	V
VR_TT# Low Output Resistance	R _{TT}	I = 20mA		6.5	9	Ω
CLK_EN# OUTPUT LEVELS	ł	1		1	+	
CLK_EN# Low Output Voltage	V _{OL}	I = 4mA		0.26	0.4	V
CLK_EN# Leakage Current	I _{OH}	CLK_EN# = 3.3V	-1		1	μA
CURRENT MONITOR	1		I	r		
IMON Output Current	IIMON	ISUM- pin current = $20\mu A$	108	120	132	μA
		ISUM- pin current = $10\mu A$	51	60	69	μA
		ISUM- pin current = $5\mu A$		30		μA
IMON Clamp Voltage	VIMONCLAMP			1.1	1.15	V
Current Sinking Capability				275		μA
INPUTS		<u>.</u>	I	1	1	
VR_ON Leakage Current	I _{VR_ON}	$VR_ON = OV$	-1	0		μA
		VR_ON = 1V		0	1	μA
VIDx Leakage Current	I _{VIDx}	VIDx = 0V	-1	0		μA
		VIDx = 1V		0.45	1	μA
PSI# Leakage Current	I _{PSI#}	PSI# = OV	-1	0		μA
		PSI# = 1V		0.45	1	μA
DPRSLPVR Leakage Current	IDPRSLPVR	DPRSLPVR = 0V	-1	0		μA
		DPRSLPVR = 1V		0.45	1	μA
SLEW RATE	1		I.	J		
Slew Rate (For VID Change)	SR		5		6.5	mV/µs

NOTE:

6. Compliance to datasheet limits is assured by one or more methods: production test, characterization and/or design.

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Gate Driver Timing Diagram



Simplified Application Circuits

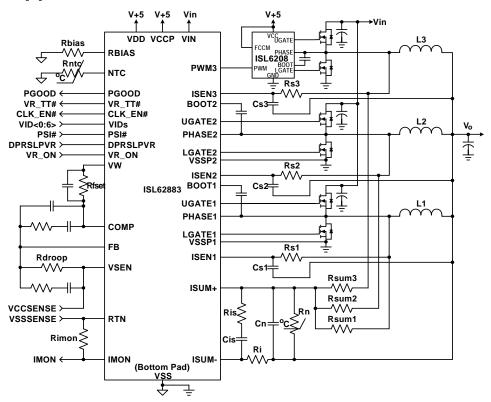
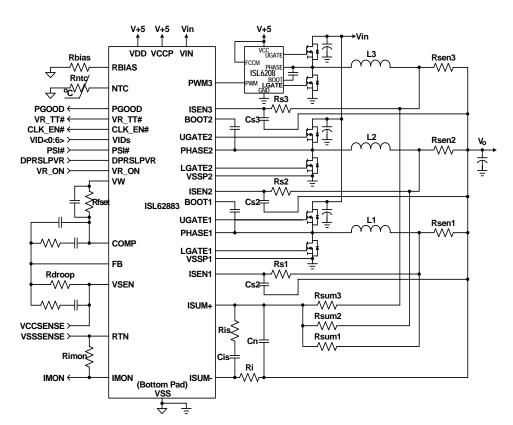


FIGURE 1. TYPICAL APPLICATION CIRCUIT USING DCR SENSING





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Theory of Operation

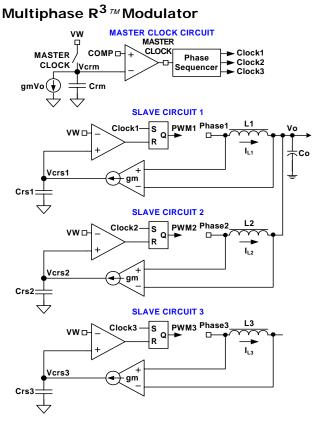
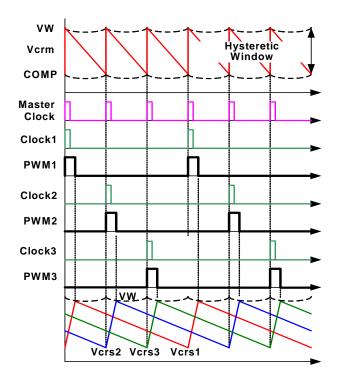


FIGURE 3. R^{3™} MODULATORCIRCUIT





Vcrm Master Clock Clock1 PWM1 Clock2 PWM2 Clock3 PWM3 Vcrs1 Vcrs1 Vcrs1

FIGURE 5. R³™ MODULATOROPERATION PRINCIPLES IN LOAD INSERTION RESPONSE

The ISL62883 is a multiphase regulators implementing Intel[™] IMVP-6.5[™] protocol. It can be programmed for 1-, 2- or 3-phase operation for microprocessor core applications. It uses Intersil patented $R^{3™}$ (Robust Ripple Regulator[™]) modulator. The $R^{3™}$ modulator combines the best features of fixed frequency PWM and hysteretic PWM while eliminating many of their shortcomings. Figure 3 conceptually shows the ISL62883 multiphase $R^{3™}$ modulator circuit, and Figure 4 shows the operation principles.

A current source flows from the VW pin to the COMP pin, creating a voltage window set by the resistor between the two pins. This voltage window is called VW window in the following discussion.

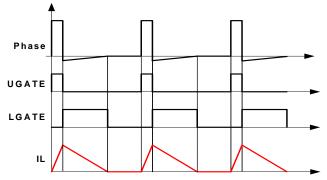
Inside the IC, the modulator uses the master clock circuit to generate the clocks for the slave circuits. The modulator discharges the ripple capacitor C_{rm} with a current source equal to $g_{m}V_{o^{\textrm{,}}}$ where g_{m} is a gain factor. C_{rm} voltage V_{crm} is a sawtooth waveform traversing between the VW and COMP voltages. It resets to VW when it hits COMP, and generates a one-shot master clock signal. A phase sequencer distributes the master clock signal to the slave circuits. If the ISL62883 is in 3-phase mode, the master clock signal will be distributed to the three phases, and the Clock1~3 signals will be 120° out-of-phase. If the ISL62883 is in 2-phase mode, the master clock signal will be distributed to Phases 1 and 2, and the Clock1 and Clock2 signals will be 180° out-of-phase. If the ISL62883 is in 1-phase mode, the master clock signal will be distributed to Phases 1 only and be the Clock1 signal.

Each slave circuit has its own ripple capacitor C_{rs} , whose voltage mimics the inductor ripple current. A g_m amplifier converts the inductor voltage into a current source to charge and discharge C_{rs} . The slave circuit turns on its PWM pulse upon receiving the clock signal, and the current source charges C_{rs} . When C_{rs} voltage V_{Crs} hits VW, the slave circuit turns off the PWM pulse, and the current source discharges C_{rs} .

Since the ISL62883 works with V_{CTS} , which are largeamplitude and noise-free synthesized signals, the ISL62883 achieves lower phase jitter than conventional hysteretic mode and fixed PWM mode controllers. Unlike conventional hysteretic mode converters, the ISL62883 has an error amplifier that allows the controller to maintain a 0.5% output voltage accuracy.

Figure 5 shows the operation principles during load insertion response. The COMP voltage rises during load insertion, generating the master clock signal more quickly, so the PWM pulses turn on earlier, increasing the effective switching frequency, which allows for higher control loop bandwidth than conventional fixed frequency PWM controllers. The VW voltage rises as the COMP voltage rises, making the PWM pulses wider. During load release response, the COMP voltage falls. It takes the master clock circuit longer to generate the next master clock signal so the PWM pulse is held off until needed. The VW voltage falls as the VW voltage falls, reducing the current PWM pulse width. This kind of behavior gives the ISL62883 excellent response speed.

The fact that all the phases share the same VW window voltage also ensures excellent dynamic current balance among phases.



Diode Emulation and Period Stretching

FIGURE 6. DIODE EMULATION

ISL62883 can operate in diode emulation (DE) mode to improve light load efficiency. In DE mode, the low-side MOSFET conducts when the current is flowing from source to drain and doesn't not allow reverse current, emulating a diode. As Figure 6 shows, when LGATE is on, the low-side MOSFET carries current, creating negative voltage on the phase node due to the voltage drop across the ON-resistance. The ISL62883 monitors the current through monitoring the phase node voltage. It turns off LGATE when the phase node voltage reaches

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zero to prevent the inductor current from reversing the direction and creating unnecessary power loss.

If the load current is light enough, as Figure 6 shows, the inductor current will reach and stay at zero before the next phase node pulse, and the regulator is in discontinuous conduction mode (DCM). If the load current is heavy enough, the inductor current will never reach OA, and the regulator is in CCM although the controller is in DE mode.

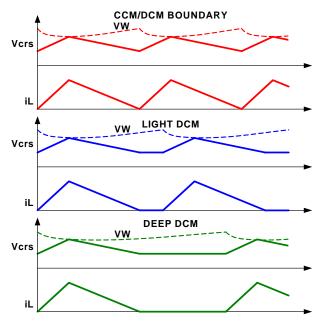




Figure 7 shows the operation principle in diode emulation mode at light load. The load gets incrementally lighter in the three cases from top to bottom. The PWM on-time is determined by the VW window size, therefore is the same, making the inductor current triangle the same in the three cases. The ISL62883 clamps the ripple capacitor voltage V_{crs} in DE mode to make it mimic the inductor current. It takes the COMP voltage longer to hit V_{crs}, naturally stretching the switching period. The inductor current triangles move further apart from each other such that the inductor current average value is equal to the load current. The reduced switching frequency helps increase light load efficiency.

Start-up Timing

With the controller's V_{DD} voltage above the POR threshold, the start-up sequence begins when VR_ON exceeds the 3.3V logic high threshold. The ISL62883 uses digital soft start to ramp up DAC to the boot voltage of 1.1V at about 2.5mV/µs. Once the output voltage is within 10% of the boot voltage for 13 PWM cycles (43µs for frequency = 300kHz), CLK_EN# is pulled low and DAC slews at 5mV/µs to the voltage set by the VID pins. PGOOD is asserted high in approximately 7ms. Figure 8 shows the typical start-up timing. Similar results occur if

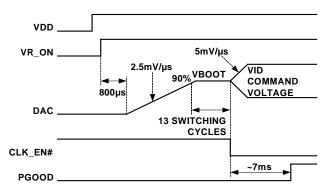


FIGURE 8. SOFT-START WAVEFORMS

VR_ON is tied to V_DD, with the soft-start sequence starting 120 μs after V_DD crosses the POR threshold

Voltage Regulation and Load Line Implementation

After the start sequence, the ISL62883 regulates the output voltage to the value set by the VID inputs per Table 1. The ISL62883 will control the no-load output voltage to an accuracy of $\pm 0.5\%$ over the range of 0.75V to 1.5V. A differential amplifier allows voltage sensing for precise voltage regulation at the microprocessor die.

VID6	VID5	VID4	VID3	VID2	VID1	VIDO	V _O (V)		
0	0	0	0	0	0	0	1.5000		
0	0	0	0	0	0	1	1.4875		
0	0	0	0	0	1	0	1.4750		
0	0	0	0	0	1	1	1.4625		
0	0	0	0	1	0	0	1.4500		
0	0	0	0	1	0	1	1.4375		
0	0	0	0	1	1	0	1.4250		
0	0	0	0	1	1	1	1.4125		
0	0	0	1	0	0	0	1.4000		
0	0	0	1	0	0	1	1.3875		
0	0	0	1	0	1	0	1.3750		
0	0	0	1	0	1	1	1.3625		
0	0	0	1	1	0	0	1.3500		
0	0	0	1	1	0	1	1.3375		
0	0	0	1	1	1	0	1.3250		
0	0	0	1	1	1	1	1.3125		
0	0	1	0	0	0	0	1.3000		
0	0	1	0	0	0	1	1.2875		
0	0	1	0	0	1	0	1.2750		
0	0	1	0	0	1	1	1.2625		
0	0	1	0	1	0	0	1.2500		
0	0	1	0	1	0	1	1.2375		
0	0	1	0	1	1	0	1.2250		

TABLE 1. VID TABLE

TABLE 1. VID TABLE (Continued)

VHOMVIDMVIDMVIDMVIDMVIDMVIDM00.01.01.01.01.01.000.01.01.00.01.01.000.01.10.01.01.11.100.01.10.01.11.11.100.01.11.01.11.11.11.100.01.11.11.11.11.11.100.01.11.11.11.11.11.100.01.11.11.11.11.11.100.01.11.11.11.11.11.100.11.11.11.11.11.11.100.11.11.11.11.11.11.100.11.11.11.11.11.11.1001.11.11.11.11.11.101.11.11.11.11.11.11.101.11.11.11.11.11.11.101.11.11.11.11.11.11.101.11.11.11.11.11.11.101.11.11.11.11.11.11.101.11.11.11.11.11.11.101.11	TABLE 1. VID TABLE (Continued)									
0011001.20000011011.18750011011.1500011011.162500111011.150000111001.150000111111.12500011111.12501.125000111111.125001000011.12500100011.12500100011.12500100011.12500100011.12500100011.0250100011.0250100111.0250100111.0250100111.0250101111.02501011110101111.0250101111010111	VID6	VID5	VID4	VID3	VID2	VID1	VIDO	V _O (V)		
00110011.187500110101.1500011011.162500111011.137500111101.15000011111.13751.125000111111.125101011111.125101000011.102501000011.00510100011.00510100011.01500100101.05010100101.05010100111.02510100111.02510100111.02510100111.02510100111.02510101111010111101011110101111010 <td>0</td> <td>0</td> <td>1</td> <td>0</td> <td>1</td> <td>1</td> <td>1</td> <td>1.2125</td>	0	0	1	0	1	1	1	1.2125		
00110101.11.162500111011.162500111001.150000111001.125000111111.12500111111.1250100001.12500100001.12500100001.12500100001.12500100011.02510100101.0500100101.02510100111.02510100111.02510100111.02510100111.02510101011.02510101111.025101011110101110101110101110101110	0	0	1	1	0	0	0	1.2000		
0011011.162500111001.150000111101.125000111101.125000111111.11250100001.125001000011.112501000011.0070100011.0070100011.0070100111.0250100111.0250100111.02501010111.02501010111.02501010111.02501010111.02501010111.02501010111.02501011011.02501011011.02501011111.02501011<	0	0	1	1	0	0	1	1.1875		
N 01110110011101100111111001111110000001010001000010100010001100010001100010011010001001101000100110100010011010001010110001010110001010110001010100101010010101001010100101010010110001011000101100011001001101	0	0	1	1	0	1	0	1.1750		
0011101.13750011111.12500011111.12510100001.000100001.0100010001.0100010001.0100010011.0250010011.0250010011.0250010011.0250010101.0250010101.0250010101.0250010101.0250010101.0250010101.0250010101.0250010101.0250010101.0250010101.0250010101.0250010101.0250010101.0250010101010101.02500101100 </td <td>0</td> <td>0</td> <td>1</td> <td>1</td> <td>0</td> <td>1</td> <td>1</td> <td>1.1625</td>	0	0	1	1	0	1	1	1.1625		
00111111100111111.11250100001.10000100001.10010100011.08750100011.050010011.0150010011.0150010011.0250010011.015501011.0111.0250010101.0155010101.025001010.01.025001010.01.025001010.01.025001010.01.025001010.01.025001010.01.025001010.01.025001010.01.025001010.01.001010.01.001010.01.0010100.001011001 </td <td>0</td> <td>0</td> <td>1</td> <td>1</td> <td>1</td> <td>0</td> <td>0</td> <td>1.1500</td>	0	0	1	1	1	0	0	1.1500		
00111111111010000011.00001000011.08750100011.050010011.011.0250100101.050010010.01.050010011.011.025010011.011.025010011.011.025010101.011.025010101.011.025010101.011.025010101.011.025010101.011.025010101.011.0250101010.93750101100.94500101100.94500101110.94550110110.945501100110101100011 <td>0</td> <td>0</td> <td>1</td> <td>1</td> <td>1</td> <td>0</td> <td>1</td> <td>1.1375</td>	0	0	1	1	1	0	1	1.1375		
01000001.1000100011.087501001011.087501001011.05201001011.062501001011.0520100111.03750100111.02500100111.025001010111.025001010111.02500101011.02500101010.02500101010.937501011000.905001011000.925001011100.925001011100.925001011100.925001011100.925001100100.925001100100.92500110 <td>0</td> <td>0</td> <td>1</td> <td>1</td> <td>1</td> <td>1</td> <td>0</td> <td>1.1250</td>	0	0	1	1	1	1	0	1.1250		
01000011.087501001011.07500100111.0625010010011.062501001011.0500100111.03750100111.02500100111.025001010111.025001010111.025001010111.02500101010.097500101010.93750101100.95000101100.95000101110.912501011100.95000110010.91250110010.92500110010.92500110010.92500110010.92500110010.82500 <t< td=""><td>0</td><td>0</td><td>1</td><td>1</td><td>1</td><td>1</td><td>1</td><td>1.1125</td></t<>	0	0	1	1	1	1	1	1.1125		
01000101.07500100111.062501001001.050001001011.037501001111.037501001111.025001001111.0125010101011.0125010101010.0875010101010.987501011010.962501011000.950001011000.925001011100.92500110110.91250110010.92500110010.82500110010.825101101100.850001101100.825001101100.825001101100.8250	0	1	0	0	0	0	0	1.1000		
010011.06250100101.05000100101.03750100111.03750100111.02500100111.012501010101.025001010101.00000101010.097500101010.93750101100.95000101100.95000101100.92500101100.92500101100.92500101100.92500101100.925001100001100000.92500110000011000001100000110010.82510110100001 <t< td=""><td>0</td><td>1</td><td>0</td><td>0</td><td>0</td><td>0</td><td>1</td><td>1.0875</td></t<>	0	1	0	0	0	0	1	1.0875		
0100101011.037501001101.025001001111.012501001111.0125010100011.000001010001.000001010001.000001010001.000001010001.000001010000.987501011000.950001011000.950001011000.92500101110.93750101110.92500101110.925001100000.925001100000.925001100000.92500110010.82510110110001101000	0	1	0	0	0	1	0	1.0750		
0100101011.037501001101.025001001111.0125010010010.00001010001.000001010010.9875010101010.9750010101100.950001011000.950001011000.95050101100.92500101100.92500101100.925001011000.925001100000.925001100000.925001100000.925001100000.925001100000.82500110100001101100.825001101<	0	1	0	0	0	1	1	1.0625		
010011010101111.012501010001.000001010010.9875010101010.9750010101010.962501011010.950001011000.950001011000.925001011100.92500101110.93750101110.925001011000.925001100000.925001100000.925001100000.925001100000.925001100000.925001100000.825001101010.8250011011000.82500110100	0	1	0	0	1	0	0	1.0500		
0100111.012501010001.000001010010.9875010101010.9750010101010.9750010101010.942501011000.950001011000.925001011100.925001011100.92500101110.912501100000.925001100000.900001100000.925001100000.900001100000.900001100000.825001101100.825001101100.825001101100.825001110000.750001110	0	1	0	0	1	0	1	1.0375		
0 1 0 1 0 0 0 1.0000 0 1 0 1 0 0 1 0.9875 0 1 0 1 0 1 0 0.9750 0 1 0 1 0 1 0 0.9750 0 1 0 1 0 1 0 0.9750 0 1 0 1 1 0 0.9750 0 1 0 1 1 0 0.9625 0 1 0 1 1 0.9375 0 1 0 1 1 0.9375 0 1 0 1 1 0.9375 0 1 0 1 1 0.9375 0 1 1 0 0 0.9050 0 1 1 0 0 0.8375 0	0	1	0	0	1	1	0	1.0250		
0 1 0 1 0 0 1 0.9875 0 1 0 1 0 1 0 1 0.9750 0 1 0 1 0 1 0 1 0.9625 0 1 0 1 1 0 0.9500 0 1 0 1 1 0 0.9500 0 1 0 1 1 0 0.9500 0 1 0 1 1 0 0.9250 0 1 0 1 1 0.9125 0 1 1 0 0 0 0.9000 0 1 1 0 0 0 0.9000 0 1 1 0 0 0 0.8075 0 1 1 0 1 0.8375 0 1 1 0 1	0	1	0	0	1	1	1	1.0125		
0 1 0 1 0 1 0 1 0 9750 0 1 0 1 0 1 0 1 0 9750 0 1 0 1 1 0 0 99500 0 1 0 1 1 0 0 99505 0 1 0 1 1 0 0 99505 0 1 0 1 1 0 99505 0 1 0 1 1 0 99505 0 1 0 1 1 0 99505 0 1 1 0 0 0 99005 0 1 1 0 0 0 99005 0 1 1 0 0 0 99005 0 1 1 0 0 0 99005	0	1	0	1	0	0	0	1.0000		
0 1 0 1 0 1 0.9625 0 1 0 1 1 0 0.9500 0 1 0 1 1 0 0.9500 0 1 0 1 1 0 0.9375 0 1 0 1 1 1 0.9375 0 1 0 1 1 1 0.9375 0 1 0 1 1 0.9020 0.9020 0 1 0 0 0 0 9.9020 0 1 1 0 0 1 0.8875 0 1 1 0 0 1 0.8875 0 1 1 0 1 0.8625 0 1 1 0 1 0.8375 0 1 1 0 1 0.8375 0 1	0	1	0	1	0	0	1	0.9875		
0 1 0 1 1 0 0 0.9500 0 1 0 1 1 0 1 0.9375 0 1 0 1 1 1 0 0.9250 0 1 0 1 1 1 1 0.9250 0 1 0 1 1 1 1 0.9250 0 1 0 0 0 0 0.9250 0 1 0 0 0 0 9000 0 1 0 0 0 1 0.8875 0 1 1 0 1 0 0.8875 0 1 1 0 1 0.8625 0 1 0.8375 0 1 1 0 1 0 0 0.8250 0 1 1 0 1 0.8375 0 0 </td <td>0</td> <td>1</td> <td>0</td> <td>1</td> <td>0</td> <td>1</td> <td>0</td> <td>0.9750</td>	0	1	0	1	0	1	0	0.9750		
0 1 0 1 1 0 1 0.9375 0 1 0 1 1 1 0 0.9250 0 1 0 1 1 1 0 0.9250 0 1 0 0 0 0 0 0.9125 0 1 1 0 0 0 0 0.9000 0 1 1 0 0 0 1 0.8875 0 1 1 0 0 1 0.8875 0 1 1 0 1 0 0.8875 0 1 1 0 1 0.8625 0 1 1 0 1 0.8500 0 1 1 0 1 0.8250 0 1 1 0 1 0.8250 0 1 1 0 0 0.7875	0	1	0	1	0	1	1	0.9625		
0 1 0 1 1 1 0 0.9250 0 1 0 1 1 1 1 0.9125 0 1 1 0 0 0 0 0.9000 0 1 1 0 0 0 1 0.8875 0 1 1 0 0 1 0.8875 0 1 1 0 0 1 0.8875 0 1 1 0 0 1 0.8625 0 1 1 0 1 0 0.8500 0 1 1 0 1 0.8375 0 1 1 0 1 0.8375 0 1 1 0 1 0.8375 0 1 1 0 1 0.8375 0 1 1 0 0 0.7875 0	0	1	0	1	1	0	0	0.9500		
0 1 0 1 1 1 1 0.9125 0 1 1 0 0 0 0 0.9000 0 1 1 0 0 0 1 0.8875 0 1 1 0 0 1 0.8875 0 1 1 0 0 1 0.8625 0 1 1 0 1 0 0.8500 0 1 1 0 1 0 0.8500 0 1 1 0 1 0 0.8375 0 1 1 0 1 0.8375 0 1 1 0 1 0.8375 0 1 1 0 0 0.8000 0 1 1 0 0 0.7875 0 1 1 1 0 0.7625 0 1	0	1	0	1	1	0	1	0.9375		
0 1 1 0 0 0 0 0 0.9000 0 1 1 0 0 0 1 0.8875 0 1 1 0 0 1 0.8750 0 1 1 0 0 1 0.8625 0 1 1 0 1 0 0 1 0.8625 0 1 1 0 1 0 0 0 0.8500 0 1 1 0 1 0 0 0.8500 0 1 1 0 1 0 0.8500 0 1 1 0 1 0.8375 0 1 1 0 1 0.8250 0 1 1 0 0 0.8000 0 1 1 0 0 0.7875 0 1 1 1	0	1	0	1	1	1	0	0.9250		
0 1 1 0 0 0 1 0.8875 0 1 1 0 0 1 0 0.8750 0 1 1 0 0 1 1 0.8625 0 1 1 0 1 0 0 1 0.8625 0 1 1 0 1 0 0 0.8500 0 1 1 0 1 0 1 0.8375 0 1 1 0 1 1 0.8375 0 1 1 0 1 1 0.8375 0 1 1 0 1 0.8250 0 1 1 0 0 0 0.8000 0 1 1 0 0 0 0.7875 0 1 1 1 0 0 0.7375 0 1	0	1	0	1	1	1	1	0.9125		
0 1 1 0 0 1 0 0.8750 0 1 1 0 0 1 1 0.8625 0 1 1 0 1 0 0 1 1 0.8625 0 1 1 0 1 0 0 0.8500 0 1 1 0 1 0 0 0.8375 0 1 1 0 1 1 0.8375 0 1 1 0 1 1 0.8375 0 1 1 0 1 0.8250 0 1 1 0 0 0.8250 0 1 1 0 0 0.800 0 1 1 0 0 0.70750 0 1 1 1 0 0.7500 0 1 1 1 1 0	0	1	1	0	0	0	0	0.9000		
0 1 1 0 0 1 1 0.8625 0 1 1 0 1 0 0 0 0.8500 0 1 1 0 1 0 0 0.8500 0 1 1 0 1 0 1 0.8375 0 1 1 0 1 1 0 1.8375 0 1 1 0 1 1 0 0.8250 0 1 1 0 1 1 0.8125 0 1 1 0 0 0 0.8000 0 1 1 0 0 0 0.7875 0 1 1 1 0 0 0.7625 0 1 1 1 1 0 0.7375 0 1 1 1 1 0 0.7250 0	0	1	1	0	0	0	1	0.8875		
0 1 0 1 0 0 0.8500 0 1 1 0 1 0 1 0.8375 0 1 1 0 1 1 0 1 0.8375 0 1 1 0 1 1 0 0.8250 0 1 1 0 1 1 0 0.8250 0 1 1 0 1 1 0 0.8250 0 1 1 0 1 1 0.8125 0 1 1 0 0 0 0.8000 0 1 1 0 0 0 0.7875 0 1 1 1 0 0 0.7750 0 1 1 1 0 0 0.7375 0 1 1 1 1 0 0.7250 0 1	0	1	1	0	0	1	0	0.8750		
0 1 1 0 1 0 1 0.8375 0 1 1 0 1 1 0 1 0.8375 0 1 1 0 1 1 0 0.8250 0 1 1 0 1 1 0 0.8250 0 1 1 0 1 1 0 0.8250 0 1 1 0 0 0 0.8250 0 1 1 0 0 0 0.8250 0 1 1 0 0 0 0.8000 0 1 1 0 0 0.7875 0 1 1 1 0 0.7625 0 1 1 1 0 0.7375 0 1 1 1 0 0.7250 0 1 1 1 1 0	0	1	1	0	0	1	1	0.8625		
0 1 1 0 1 1 0 0.8250 0 1 1 0 1 1 0 0.8250 0 1 1 0 1 1 1 0.8125 0 1 1 1 0 0 0 0.8000 0 1 1 1 0 0 0 0.8000 0 1 1 1 0 0 0 0.8000 0 1 1 0 0 0 0.7875 0 1 1 1 0 0 0.7750 0 1 1 1 0 0 0.7500 0 1 1 1 1 0 0.7250 0 1 1 1 1 0 0.7250 0 1 1 1 1 1 0.7125 0 0	0	1	1	0	1	0	0	0.8500		
0 1 1 0 1 1 1 0.8125 0 1 1 0 0 0 0.8000 0 1 1 0 0 0 0.8000 0 1 1 0 0 1 0.7875 0 1 1 0 1 0 0.7750 0 1 1 1 0 1 0.7625 0 1 1 1 0 0 0.7500 0 1 1 1 0 0 0.7500 0 1 1 1 0 0 0.7500 0 1 1 1 0 0.7375 0 1 1 1 1 0 0.7250 0 1 1 1 1 0 0.7125 0 1 1 1 1 1 0.7000	0	1	1	0	1	0	1	0.8375		
0 1 1 0 0 0 0.8000 0 1 1 0 0 1 0.7875 0 1 1 0 0 1 0.7875 0 1 1 0 1 0.7875 0 1 1 0 1 0 0.7750 0 1 1 1 0 1 0 0.7625 0 1 1 1 0 1 0.7625 0 1 1 1 0 0.7500 0 1 1 1 0 0.7375 0 1 1 1 0 0.7250 0 1 1 1 1 0.7125 0 1 1 1 1 0.7000 1 0 0 0 0 0.7000	0	1	1	0	1	1	0	0.8250		
0 1 1 0 0 1 0.7875 0 1 1 0 1 0.7875 0 1 1 0 1 0.7875 0 1 1 0 1 0 0.7750 0 1 1 0 1 1 0.7625 0 1 1 1 0 0 0.7500 0 1 1 1 0 0 0.7500 0 1 1 1 0 0 0.7500 0 1 1 1 0 0 0.7500 0 1 1 1 0 0.7250 0 1 1 1 1 0 0.7250 0 1 1 1 1 1 0.7125 1 0 0 0 0 0 0.7000	0	1	1	0	1	1	1	0.8125		
0 1 1 0 1 0 0.7750 0 1 1 1 0 1 0 0.7750 0 1 1 1 0 1 1 0.7625 0 1 1 1 1 0 0 0.7500 0 1 1 1 1 0 0 0.7500 0 1 1 1 1 0 0 0.7375 0 1 1 1 1 0 0.7250 0 1 1 1 1 0 0.7250 0 1 1 1 1 0.7125 1 0 0 0 0 0.7000	0	1	1	1	0	0	0	0.8000		
0 1 1 0 1 1 0.7625 0 1 1 1 0 1 1 0.7625 0 1 1 1 1 0 0 0.7500 0 1 1 1 1 0 0 0.7500 0 1 1 1 0 1 0.7375 0 1 1 1 1 0 0.7250 0 1 1 1 1 0 0.7250 0 1 1 1 1 0 0.7250 1 1 1 1 1 0.7125 1 0 0 0 0 0 0.7000	0	1	1	1	0	0	1	0.7875		
0 1 1 1 0 0 0.7500 0 1 1 1 0 0 0.7500 0 1 1 1 0 1 0.7375 0 1 1 1 1 0 0.7250 0 1 1 1 1 0 0.7125 1 0 0 0 0 0 0.7000	0	1	1	1	0	1	0	0.7750		
0 1 1 1 0 1 0.7375 0 1 1 1 0 1 0.7375 0 1 1 1 1 0 0.7250 0 1 1 1 1 0 0.7250 0 1 1 1 1 0 0.7125 1 0 0 0 0 0 0.7000	0	1	1	1	0	1	1	0.7625		
0 1 1 1 1 0 0.7250 0 1 1 1 1 0 0.7250 1 1 1 1 1 0 0.7250 1 1 1 1 1 0.7125 1 0 0 0 0 0 0.7000	0	1	1	1	1	0	0	0.7500		
0 1 1 1 1 0.7125 1 0 0 0 0 0 0.7000	0	1	1	1	1	0	1	0.7375		
1 0 0 0 0 0 0 0 0.7000	0	1	1	1	1	1	0	0.7250		
	0	1	1	1	1	1	1	0.7125		
1 0 0 0 0 0 1 0.6875	1	0	0	0	0	0	0	0.7000		
	1	0	0	0	0	0	1	0.6875		

TABLE 1. VID TABLE (Continued)

VID6	VID5	VID4	VID3	VID2	VID1	VIDO	V _O (V)
1	0	0	0	0	1	0	0.6750
1	0	0	0	0	1	1	0.6625
1	0	0	0	1	0	0	0.6500
1	0	0	0	1	0	1	0.6375
1	0	0	0	1	1	0	0.6250
1	0	0	0	1	1	1	0.6125
1	0	0	1	0	0	0	0.6000
1	0	0	1	0	0	1	0.5875
1	0	0	1	0	1	0	0.5750
1	0	0	1		1	1	
1				0			0.5625
	0	0	1		0	0	0.5500
1	0	0	1	1	0	1	0.5375
1	0	0	1	1	1	0	0.5250
1	0	0	1	1	1	1	0.5125
1	0	1	0	0	0	0	0.5000
1	0	1	0	0	0	1	0.4875
1	0	1	0	0	1	0	0.4750
1	0	1	0	0	1	1	0.4625
1	0	1	0	1	0	0	0.4500
1	0	1	0	1	0	1	0.4375
1	0	1	0	1	1	0	0.4250
1	0	1	0	1	1	1	0.4125
1	0	1	1	0	0	0	0.4000
1	0	1	1	0	0	1	0.3875
1	0	1	1	0	1	0	0.3750
1	0	1	1	0	1	1	0.3625
1	0	1	1	1	0	0	0.3500
1	0	1	1	1	0	1	0.3375
1	0	1	1	1	1	0	0.3250
1	0	1	1	1	1	1	0.3125
1	1	0	0	0	0	0	0.3000
1	1	0	0	0	0	1	0.2875
1	1	0	0	0	1	0	0.2750
1	1	0	0	0	1	1	0.2625
1	1	0	0	1	0	0	0.2500
1	1	0	0	1	0	1	0.2375
1	1	0	0	1	1	0	0.2250
1	1	0	0	1	1	1	0.2125
1	1	0	1	0	0	0	0.2000
1	1	0	1	0	0	1	0.1875
1	1	0	1	0	1	0	0.1750
1	1	0	1	0	1	1	0.1625
1	1	0	1	1	0	0	0.1500
L	I	1	1	I	I	<u>I</u>	<u> </u>

TABLE 1. VID TABLE (Continued)

	TABLE I. VID TABLE (Continued)									
VID6	VID5	VID4	VID3	VID2	VID1	VIDO	v _o (v)			
1	1	0	1	1	0	1	0.1375			
1	1	0	1	1	1	0	0.1250			
1	1	0	1	1	1	1	0.1125			
1	1	1	0	0	0	0	0.1000			
1	1	1	0	0	0	1	0.0875			
1	1	1	0	0	1	0	0.0750			
1	1	1	0	0	1	1	0.0625			
1	1	1	0	1	0	0	0.0500			
1	1	1	0	1	0	1	0.0375			
1	1	1	0	1	1	0	0.0250			
1	1	1	0	1	1	1	0.0125			
1	1	1	1	0	0	0	0.0000			
1	1	1	1	0	0	1	0.0000			
1	1	1	1	0	1	0	0.0000			
1	1	1	1	0	1	1	0.0000			
1	1	1	1	1	0	0	0.0000			
1	1	1	1	1	0	1	0.0000			
1	1	1	1	1	1	0	0.0000			
1	1	1	1	1	1	1	0.0000			

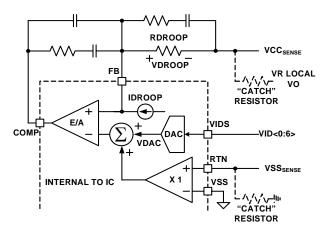


FIGURE 9. DIFFERENTIAL SENSING AND LOAD LINE IMPLEMENTATION

As the load current increases from zero, the output voltage will droop from the VID table value by an amount proportional to the load current to achieve the load line. The ISL62883 can sense the inductor current through the intrinsic DC Resistance (DCR) resistance of the inductors Figure 1 shows on page 10 or through resistors in series with the inductors as Figure 2 shows also on page 10. In both methods, capacitor C_n voltage represents the inductor total currents. A droop amplifier converts C_n voltage into an internal current source with the gain set by resistor R_i . The current source is used for load line implementation, current monitor and overcurrent protection.

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Figure 9 shows the load line implementation. The ISL62883 drives a current source I_{droop} out of the FB pin, described by Equation 1.

$$I_{droop} = \frac{2xV_{Cn}}{R_i}$$
(EQ. 1)

When using inductor DCR current sensing, a single NTC element is used to compensate the positive temperature coefficient of the copper winding thus sustaining the load line accuracy with reduced cost.

 I_{droop} flows through resistor R_{droop} and creates a voltage drop of:

$$V_{droop} = R_{droop} \times I_{droop}$$
(EQ. 2)

 V_{droop} is the droop voltage required to implement load line. Changing R_{droop} or scaling I_{droop} can both change the load line slope. Since I_{droop} also sets the overcurrent protection level, it is recommended to first scale I_{droop} based on OCP requirement, then select an appropriate R_{droop} value to obtain the desired load line slope.

Differential Sensing

Figure 9 also shows the differential voltage sensing scheme. VCCSENSE and VSSSENSE are the remote voltage sensing signals from the processor die. A unity gain differential amplifier senses the VSSSENSE voltage and add it to the DAC output. The error amplifier regulates the inverting and the non-inverting input voltages to be equal as shown in Equation 3:

$$VCC_{SENSE} + V_{droop} = V_{DAC} + VSS_{SENSE}$$
 (EQ. 3)

Rewriting Equation 3 and substitution of Equation 2 give:

$$VCC_{SENSE} - VSS_{SENSE} = V_{DAC} - R_{droop} \times I_{droop}$$
 (EQ. 4)

Equation 4 is the exact equation required for load line implementation.

The VCC_{SENSE} and VSS_{SENSE} signals come from the processor die. The feedback will be open circuit in the absence of the processor. As shown in Figure 9, it is recommended to add a "catch" resistor to feed the VR local output voltage back to the compensator, and add another "catch" resistor to connect the VR local output ground to the RTN pin. These resistors, typically $10\Omega \sim 100\Omega$, will provide voltage feedback if the system is powered up without a processor installed.

Phase Current Balancing

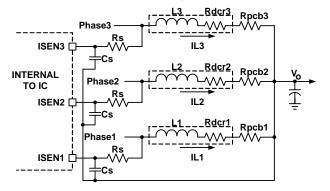


FIGURE 10. CURRENT BALANCING CIRCUIT

The ISL62883 monitors individual phase average current by monitoring the ISEN1, ISEN2, and ISEN3 voltages. Figure 10 shows the current balancing circuit recommended for ISL62883. Each phase node voltage is averaged by a low-pass filter consisting of R_s and C_s , and presented to the corresponding ISEN pin. R_s should be routed to inductor phase-node pad in order to eliminate the effect of phase node parasitic PCB DCR. Equations 5 thru 7 give the ISEN pin voltages:

$$V_{\text{ISEN1}} = (R_{\text{dcr1}} + R_{\text{pcb1}}) \times I_{\text{L1}}$$
(EQ. 5)

$$V_{ISEN2} = (R_{dcr2} + R_{pcb2}) \times I_{L2}$$
 (EQ. 6)

$$V_{ISEN3} = (R_{dcr3} + R_{pcb3}) \times I_{L3}$$
(EQ. 7)

where R_{dcr1} , R_{dcr2} and R_{dcr3} are inductor DCR; R_{pcb1} , R_{pcb2} and R_{pcb3} are parasitic PCB DCR between the inductor output side pad and the output voltage rail; and I_{L1} , I_{L2} and I_{L3} are inductor average currents.

The ISL62883 will adjust the phase pulse-width relative to the other phases to make $V_{ISEN1} = V_{ISEN2} = V_{ISEN3}$, thus to achieve $I_{L1} = I_{L2} = I_{L3}$, when there are $R_{dcr1} = R_{dcr2} = R_{dcr3}$ and $R_{pcb1} = R_{pcb2} = R_{pcb3}$.

Using same components for L1, L2 and L3 will provide a good match of R_{dcr1} , R_{dcr2} and R_{dcr3} . Board layout will determine R_{pcb1} , R_{pcb2} and R_{pcb3} . It is recommended to have symmetrical layout for the power delivery path between each inductor and the output voltage rail, such that $R_{pcb1} = R_{pcb2} = R_{pcb3}$.

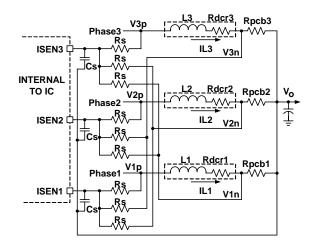


FIGURE 11. DIFFERENTIAL-SENSING CURRENT BALANCING CIRCUIT

Sometimes, it is difficult to implement symmetrical layout. For the circuit shown in Figure 10, asymmetric layout causes different R_{pcb1} , R_{pcb2} and R_{pcb3} thus current imbalance. Figure 11 shows a differential-sensing current balancing circuit recommended for ISL62883. The current sensing traces should be routed to the inductor pads so they only pick up the inductor DCR voltage. Each ISEN pin sees the average voltage of three sources: its own phase inductor pads. Equations 8 thru 10 give the ISEN pin voltages:

$$V_{ISEN1} = V_{1p} + V_{2n} + V_{3n}$$
 (EQ. 8)

$$V_{ISEN2} = V_{1n} + V_{2p} + V_{3n}$$
 (EQ. 9)

$$V_{ISEN3} = V_{1n} + V_{2n} + V_{3p}$$
 (EQ. 10)

The ISL62883 will make V_{ISEN1} = V_{ISEN2} = V_{ISEN3} as in:

$$V_{1p} + V_{2n} + V_{3n} = V_{1n} + V_{2p} + V_{3n}$$
 (EQ. 11)

$$V_{1n} + V_{2p} + V_{3n} = V_{1n} + V_{2n} + V_{3p}$$
 (EQ. 12)

Rewriting Equation 11 gives:

$$V_{1p} - V_{1n} = V_{2p} - V_{2n}$$
 (EQ. 13)

and rewriting Equation 12 gives:

$$V_{2p} - V_{2n} = V_{3p} - V_{3n}$$
 (EQ. 14)

Combining Equations 13 and 14 gives:

$$V_{1p} - V_{1n} = V_{2p} - V_{2n} = V_{3p} - V_{3n}$$
 (EQ. 15)

Therefore:

$$R_{dcr1} \times I_{L1} = R_{dcr2} \times I_{L2} = R_{dcr3} \times I_{L3}$$
 (EQ. 16)

Current balancing $(I_{L1} = I_{L2} = I_{L3})$ will be achieved when there is $R_{dcr1} = R_{dcr2} = R_{dcr3}$. R_{pcb1} , R_{pcb2} and R_{pcb3} will not have any effect.

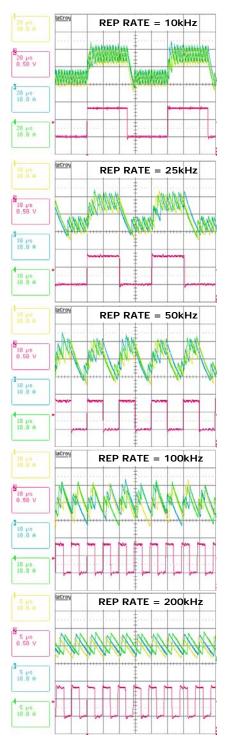


FIGURE 12. ISL62883 EVALUATION BOARD CURRENT BALANCING DURING DYNAMIC OPERATION. CH1: IL1, CH2: I_{LOAD}, CH3: IL2, CH4: IL3

Since the slave ripple capacitor voltages mimic the inductor currents, $R^{3_{TM}}$ modulator can naturally achieve excellent current balancing during steady state and dynamic operations. Figure 12 shows current balancing performance of the ISL62883 evaluation board with load transient of 12A/51A at different rep rates. The inductor currents follow the load current dynamic change with the output capacitors supplying the difference. The inductor currents can track the load current well at low rep rate, but cannot keep up when the rep rate gets into the hundred-kHz range, where it's out of the control loop bandwidth. The controller achieves excellent current balancing in all cases.

CCM Switching Frequency

The R_{fset} resistor between the COMP and the VW pins sets the sets the VW windows size, therefore sets the switching frequency. When the ISL62883 is in continuous conduction mode (CCM), the switching frequency is not absolutely constant due to the nature of the R^{3TM} modulator. As explained in the Multiphase R^{3™} Modulator section, the effective switching frequency will increase during load insertion and will decrease during load release to achieve fast response. On the other hand, the switching frequency is relatively constant at steady state. Variation is expected when the power stage condition, such as input voltage, output voltage, load, etc. changes. The variation is usually less than 15% and doesn't have any significant effect on output voltage ripple magnitude. Equation 17 gives an estimate of the frequency-setting resistor R_{fset} value. 8kΩ R_{fset} gives approximately 300kHz switching frequency. Lower resistance gives higher switching frequency.

 $R_{fset}(k\Omega) = (Period(\mu s) - 0.29) \times 2.65$ (EQ. 17)

Phase Count Configurations

The ISL62883 can be configured for 3-, 2- or 1-phase operation.

For 2-phase configuration, tie the PWM3 pin to 5V. Phase-1 and Phase-2 PWM pulses are 180° out-of-phase. In this configuration, the ISEN3/FB2 pin (pin 9) serves the FB2 function.

For 1-phase configuration, tie the PWM3 and ISEN2 pins to 5V. In this configuration, only Phase-1 is active. The ISEN3/FB2, ISEN2, and ISEN1 pins are not used because there is no need for either current balancing or FB2 function.

Modes of Operation

TABLE 2. ISL62883 MODES OF OPERATION

CONFIGURATION	PSI#	DPRSLPVR	OPERATIONAL MODE
3-phase	0	0	2-phase CCM
Configuration	0	1	1-phase DE
	1	0	3-phase CCM
	1	1	1-phase DE
2-phase	0	0	1-phase CCM
Configuration	0	1	1-phase DE
	1	0	2-phase CCM
	1	1	1-phase DE
1-phase	0	0	1-phase CCM
Configuration	0	1	1-phase DE
	1	0	1-phase CCM
	1	1	1-phase DE

Table 2 shows the ISL62883 operational modes, programmed by the logic status of the PSI# and the DPRSLPVR pins. In 3-phase configuration, the ISL62883 enters 2-phase CCM for (PSI# = 0 and DPRSLPVR = 0) by dropping PWM3 and operating phases 1 and 2 180° out-of-phase. It also reduces the overcurrent and the way-overcurrent protection levels to 2/3 of the initial values. The ISL62883 enters 1-phase DE mode when DPRSLPVR = 1. It drops phases 2 and 3, and reduces the overcurrent and the way-overcurrent protection levels to 1/3 of the initial values.

In 2-phase configuration, the ISL62883 enters 1-phase CCM for (PSI# = 0 and DPRSLPVR = 0). It drops phase 2 and reduces the overcurrent and the way-overcurrent protection levels to 1/2 of the initial values. The ISL62883 enters 1-phase DE mode when DPRSLPVR = 1 by dropping phase 2.

In 1-phase configuration, the ISL62883 does not change the operational mode when the PSI# signal changes status. It enters 1-phase DE mode when DPRSLPVR = 1.

Dynamic Operation

The ISL62883 responds to VID changes by slewing to the new voltage at 5mV/ μ s slew rate. As the output approaches the VID command voltage, the dv/dt moderates to prevent overshoot. Geyserville-III transitions commands one LSB VID step (12.5mV) every 2.5 μ s, controlling the effective dv/dt at 5mv/ μ s. The ISL62883 is capable of 5mV/ μ s slew rate.

When the ISL62883 is in DE mode, it will actively drive the output voltage up when the VID changes to a higher value. It'll resume DE mode operation after reaching the new voltage level. If the load is light enough to warrant DCM, it will enter DCM after the inductor current has crossed zero for four consecutive cycles. The ISL62883 will remain in DE mode when the VID changes to a lower value. The output voltage will decay to the new value and the load will determine the slew rate.

During load insertion response, the Fast Clock function increases the PWM pulse response speed. The ISL62883 monitors the VSEN pin voltage and compares it to 100ns - filtered version. When the unfiltered version is 20mV below the filtered version, the controller knows there is a fast voltage dip due to load insertion, hence issues an additional master clock signal to deliver a PWM pulse immediately.

The $R^{3_{TM}}$ modulator intrinsically has voltage feed forward. The output voltage is insensitive to a fast slew rate input voltage change.

Protections

The ISL62883 provides overcurrent, current-balance, undervoltage, overvoltage, and over-temperature protections.

The ISL62883 determines overcurrent protection (OCP) by comparing the average value of the droop current I_{droop} with an internal current source threshold. It declares OCP when I_{droop} is above the threshold for 120µs. A resistor R_{comp} from the COMP pin to GND programs the OCP current source threshold, as Table 3 shows. It is recommended to use the nominal R_{comp} value. The ISL62883 detects the R_{comp} value at the beginning of start up, and sets the internal OCP threshold accordingly. It remembers the R_{comp} value until the VR_ON signal drops below the POR threshold.

	R _{comp}		OCP THRESHOLD (µA)			
MIN. (kΩ)	ΝΟΜΙΝΑ L (kΩ)	MAX. (kΩ)	1-PHASE MODE	2-PHASE MODE	3-PHASE MODE	
	none	none	20	40	60	
320	400	480	22.7	45.3	68	
210	235	260	20.7	41.3	62	
155	165	175	18	36	54	
104	120	136	20	37.33	56	
78	85	92	22.7	38.7	58	
62	66	70	20.7	42.7	64	
45	50	55	18	44	66	

The default OCP threshold is the value when R_{comp} is not populated. It is recommended to scale the droop current I_{droop} such that the default OCP threshold gives approximately the desired OCP level, then use R_{comp} to fine tune the OCP level if necessary.

For overcurrent conditions above 2.5 times the OCP level, the PWM outputs will immediately shut off and PGOOD will go low to maximize protection. This protection is also referred to as way-overcurrent protection or fast-overcurrent protection, for short-circuit protections.

The ISL62883 monitors the ISEN pin voltages to determine current-balance protection. If the ISEN pin voltage difference is greater than 9mV for 1ms, the controller will declare a fault and latch off.

The ISL62883 will declare undervoltage (UV) fault and latch off if the output voltage is less than the VID set value by 300mV or more for 1ms. It'll turn off the PWM outputs and dessert PGOOD.

The ISL62883 has two levels of overvoltage protections. The first level of overvoltage protection is referred to as PGOOD overvoltage protection. If the output voltage exceeds the VID set value by +200mV for 1ms, the ISL62883 will declare a fault and dessert PGOOD.

The ISL62883 takes the same actions for all of the above fault protections: desertion of PGOOD and turn-off of the high-side and low-side power MOSFETs. Any residual inductor current will decay through the MOSFET body diodes. These fault conditions can be reset by bringing VR_ON low or by bringing VD below the POR threshold. When VR_ON and VDD return to their high operating levels, a soft-start will occur.

The second level of overvoltage protection is different. If the output voltage exceeds 1.55V, the ISL62883 will immediately declare an OV fault, dessert PGOOD, and turn on the low-side power MOSFETs. The low-side power MOSFETs remain on until the output voltage is pulled down below 0.85V when all power MOSFETs are turned off. If the output voltage rises above 1.55V again, the protection process is repeated. This behavior provides the maximum amount of protection against shorted high-side power MOSFETs while preventing output ringing below ground. Resetting VR_ON cannot clear the 1.55V OVP. Only resetting V_{DD} will clear it. The 1.55V OVP is active all the time when the controller is enabled, even if one of the other faults have been declared. This ensures that the processor is protected against high-side power MOSFET leakage while the MOSFETs are commanded off.

The ISL62883 has a thermal throttling feature. If the voltage on the NTC pin goes below the 1.18V OT threshold, the VR_TT# pin is pulled low indicating the need for thermal throttling to the system. No other action is taken within the ISL62883 in response to NTC pin voltage.

Table 4 summarizes the fault protections.

TABLE 4. FAULT PROTECTION SUMMARY

FAULT TYPE	FAULT DURATION BEFORE PROTECTION	PROTECTION ACTION	FAULT RESET	
Overcurrent	120µs	PWM tri-state,	VR_ON	
Way-Overcurrent (2.5xOC)	<2µs	PGOOD latched low	toggle or VDD toggle	
Overvoltage +200mV	1ms			
Undervoltage - 300mV				
Phase Current Unbalance				
Overvoltage 1.55V	Immediately	Low-side MOSFET on until V _{core} <0.85V, then PWM tri-state, PGOOD latched low.	VDD toggle	
Over-Temperature		1ms	N/A	

Current Monitor

The ISL62883 provides the current monitor function. The IMON pin outputs a high-speed analog current source that is 3 times of the droop current flowing out of the FB pin. Thus Equation 18:

$$I_{\rm IMON} = 3 \times I_{\rm droop}$$
 (EQ. 18)

As Figures 1 and 2 show, a resistor R_{imon} is connected to the IMON pin to convert the IMON pin current to voltage. A capacitor can be paralleled with R_{imon} to filter the voltage information. The IMVP-6.5TM specification requires that the IMON voltage information be referenced to VSSSENSE.

The IMON pin voltage range is 0V to 1.1V. A clamp circuit prevents the IMON pin voltage from going above 1.1V.

FB2 Function

The FB2 function is only available when the ISL62883 is in 2-phase configuration, when pin 9 serves the FB2 function instead of the ISEN3 function.

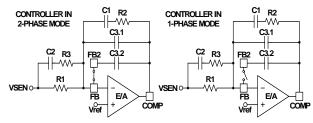


FIGURE 13. FB2 FUNCTION IN 2-PHASE MODE

Figure 13 shows the FB2 function. A switch (called FB2 switch) turns on to short the FB and the FB2 pins when the controller is in 2-phase mode. Capacitors C3.1 and C3.2 are in parallel, serving as part of the compensator.

When the controller enters 1-phase mode, the FB2 switch turns off, removing C3.2 and leaving only C3.1 in the compensator. The compensator gain will increase with the removal of C3.2. By properly sizing C3.1 and C3.2, the compensator cab be optimal for both 2-phase mode and 1-phase mode.

When the FB2 switch is off, C3.2 is disconnected from the FB pin. However, the controller still actively drives the FB2 pin voltage to follow the FB pin voltage such that C3.2 voltage always follows C3.1 voltage. When the controller turns on the FB2 switch, C3.2 will be reconnected to the compensator smoothly.

The FB2 function ensures excellent transient response in both 2-phase mode and 1-phase mode. If one decides not to use the FB2 function, simply populate C3.1 only.

Adaptive Body Diode Conduction Time Reduction

In DCM, the controller turns off the low-side MOSFET when the inductor current approaches zero. During ontime of the low-side MOSFET, phase voltage is negative and the amount is the MOSFET R_{dson} voltage drop, which is proportional to the inductor current. A phase comparator inside the controller monitors the phase voltage during on-time of the low-side MOSFET and compares it with a threshold to determine the zerocrossing point of the inductor current. If the inductor current has not reached zero when the low-side MOSFET turns off, it'll flow through the low-side MOSFET body diode, causing the phase node to have a larger voltage drop until it decays to zero. If the inductor current has crossed zero and reversed the direction when the lowside MOSFET turns off, it'll flow through the high-side MOSFET body diode, causing the phase node to have a spike until it decays to zero. The controller continues monitoring the phase voltage after turning off the lowside MOSFET and adjusts the phase comparator threshold voltage accordingly in iterative steps such that the low-side MOSFET body diode conducts for approximately 40ns to minimize the body diode-related loss.

Overshoot Reduction Function

The ISL62883 has an optional overshoot reduction function. Using R_{BIAS} = $47k\Omega$ enables this function and using R_{BIAS} = $147k\Omega$ disables this function.

When a load release occurs, the energy stored in the inductors will dump to the output capacitor, causing output voltage overshoot. The inductor current freewheels through the low-side MOSFET during this period of time. The overshoot reduction function turns off the low-side MOSFET during the output voltage overshoot, forcing the inductor current to freewheel through the low-side MOSFET body diode. Since the body diode voltage drop is much higher than MOSFET R_{dson} voltage drop, more energy is dissipated on the low-side MOSFET therefore the output voltage overshoot is lower.

If the overshoot reduction function is enabled, the ISL62883 monitors the COMP pin voltage to determine

the output voltage overshoot condition. The COMP voltage will fall and hit the clamp voltage when the output voltage overshoots. The ISL62883 will turn off LGATE1 and LGATE2, and tri-state PWM3 when COMP is being clamped. All the low-side MOSFETs in the power stage will be turned off. When the output voltage has reached its peak and starts to come down, the COMP voltage starts to rise and is no longer clamped. The ISL62883 will resume normal PWM operation.

When PSI# is low, indicating a low power state of the CPU, the controller will disable the overshoot reduction function as large magnitude transient event is not expected and overshoot is not a concern.

While the overshoot reduction function reduces the output voltage overshoot, energy is dissipated on the low-side MOSFET, causing additional power loss. The more frequent transient event, the more power loss dissipated on the low-side MOSFET. The MOSFET may face severe thermal stress when transient events happen at a high repetitive rate. User discretion is advised when this function is enabled.

Key Component Selection

RBIAS

The ISL62883 uses a resistor (1% or better tolerance is recommended) from the RBIAS pin to GND to establish highly accurate reference current sources inside the IC. Using R_{BIAS} = 47k Ω enables the overshoot reduction function and using R_{BIAS} = 147k Ω disables this function. Do not connect any other components to this pin. Do not connect any capacitor to the RBIAS pin as it will create instability.

Care should be taken in layout that the resistor is placed very close to the RBIAS pin and that a good quality signal ground is connected to the opposite side of the R_{BIAS} resistor.

Ris and Cis

As Figures 1 and 2, show, the ISL62883 needs the R_{is} - C_{is} network across the ISUM+ and the ISUM- pins to stabilize the droop amplifier. The preferred values are R_{is} = 82.5Ω and C_{is} = $0.01\mu F$. Slight deviations from the recommended values are acceptable. Large deviations may result in instability.

Inductor DCR Current-Sensing Network

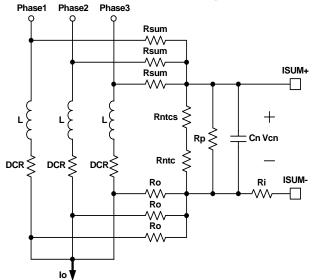


FIGURE 14. DCR CURRENT-SENSING NETWORK

Figure 14 shows the inductor DCR current-sensing network for a 3-phase solution. An inductor current flows through the DCR and creates a voltage drop. Each inductor has two resistors in R_{sum} and R_0 connected to the pads to accurately sense the inductor current by sensing the DCR voltage drop. The R_{sum} and R_0 resistors are connected in a summing network as shown, and feed the total current information to the NTC network (consisting of R_{ntcs} , R_{ntc} and R_p) and capacitor C_n . R_{ntc} is a negative temperature coefficient (NTC) thermistor, used to temperature-compensate the inductor DCR change.

The inductor output side pads are electrically shorted in the schematic, but have some parasitic impedance in actual board layout, which is why one cannot simply short them together for the current-sensing summing network. It is recommended to use $1\Omega \sim 10\Omega R_0$ to create quality signals. Since R_0 value is much smaller than the rest of the current sensing circuit, the following analysis will ignore it for simplicity.

The summed inductor current information is presented to the capacitor C_n . Equations 19 thru 23 describe the frequency-domain relationship between inductor total current $I_o(s)$ and C_n voltage $V_{Cn}(s)$:

$$V_{Cn}(s) = \left(\frac{R_{ntcnet}}{R_{ntcnet} + \frac{R_{sum}}{N}} \times \frac{DCR}{N}\right) \times I_{o}(s) \times A_{cs}(s)$$
 (EQ. 19)

$$R_{ntcnet} = \frac{(R_{ntcs} + R_{ntc}) \times R_{p}}{R_{ntcs} + R_{ntc} + R_{p}}$$
(EQ. 20)

$$A_{CS}(S) = \frac{1 + \frac{1}{\omega_L}}{1 + \frac{S}{\omega_{SNS}}}$$
(EQ. 21)

A

$$\omega_{\rm L} = \frac{\rm DCR}{\rm L} \tag{EQ. 22}$$

$$\omega_{sns} = \frac{1}{\frac{R_{ntcnet} \times \frac{R_{sum}}{N}}{R_{ntcnet} + \frac{R_{sum}}{N}} \times C_{n}}$$

(EQ. 23)

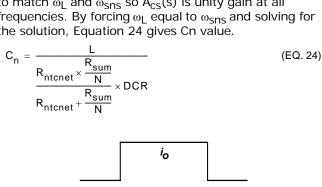
where N is the number of phases.

Transfer function $A_{CS}(s)$ always has unity gain at DC. The inductor DCR value increases as the winding temperature increases, giving higher reading of the inductor DC current. The NTC Rntc values decreases as its temperature decreases. Proper selections of R_{sum}, R_{ntcs}, R_p and R_{ntc} parameters ensure that V_{Cn} represent the inductor total DC current over the temperature range of interest.

There are many sets of parameters that can properly temperature-compensate the DCR change. Since the NTC network and the R_{sum} resistors form a voltage divider, V_{cn} is always a fraction of the inductor DCR voltage. It is recommended to have a higher ratio of V_{cn} to the inductor DCR voltage, so the droop circuit has higher signal level to work with.

A typical set of parameters that provide good temperature compensation are: $R_{sum} = 3.65 k\Omega$, $R_p = 11k\Omega$, $R_{ntcs} = 2.61k\Omega$ and $R_{ntc} = 10k\Omega$ (ERT-J1VR103J). The NTC network parameters may need to be fine tuned on actual boards. One can apply full load DC current and record the output voltage reading immediately; then record the output voltage reading again when the board has reached the thermal steady state. A good NTC network can limit the output voltage drift to within 2mV. It is recommended to follow the Intersil evaluation board layout and current-sensing network parameters to minimize engineering time.

 $V_{Cn}(s)$ also needs to represent real-time $I_0(s)$ for the controller to achieve good transient response. Transfer function $A_{CS}(s)$ has a pole ω_{SDS} and a zero ω_{I} . One needs to match ω_{l} and ω_{sns} so $A_{cs}(s)$ is unity gain at all frequencies. By forcing ω_L equal to ω_{sns} and solving for the solution, Equation 24 gives Cn value.



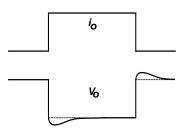


FIGURE 16. LOAD TRANSIENT RESPONSE WHEN Cn **IS TOO SMALL**

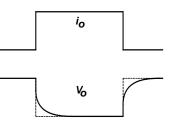


FIGURE 17. LOAD TRANSIENT RESPONSE WHEN Cn **IS TOO LARGE**

For example, given N = 3, $R_{sum} = 3.65 k\Omega$, $R_p = 11 k\Omega$, R_{ntcs} = 2.61kQ, R_{ntc} = 10kQ, DCR = 0.88mQ and L = 0.36 μ H, Equation 24 gives C_n = 0.406 μ F.

Assuming the compensator design is correct, Figure 15 shows the expected load transient response waveforms if C_n is correctly selected. When the load current I_{core} has a square change, the output voltage V_{core} also has a square response.

If C_n value is too large or too small, $V_{Cn}(s)$ will not accurately represent real-time Io(s) and will worsen the transient response. Figure 16 shows the load transient response when Cn is too small. Vcore will sag excessively upon load insertion and may create a system failure. Figure 17 shows the transient response when C_n is too large. V_{core} is sluggish in drooping to its final value. There will be excessive overshoot if load insertion occurs during this time, which may potentially hurt the CPU reliability.

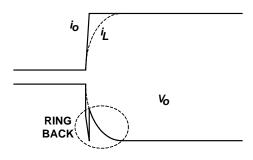


FIGURE 18. OUTPUT VOLTAGE RING BACK PROBLEM



21

6

inter_{sil}

R_{ntcnet} + -

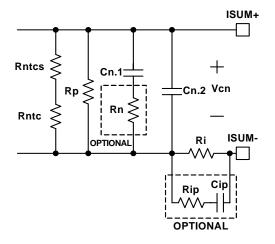


FIGURE 19. OPTIONAL CIRCUITS FOR RING BACK REDUCTION

Figure 18 shows the output voltage ring back problem during load transient response. The load current $i_{\rm O}$ has a fast step change, but the inductor current $i_{\rm L}$ cannot accurately follow. Instead, $i_{\rm L}$ responds in first order system fashion due to the nature of current loop. The ESR and ESL effect of the output capacitors makes the output voltage $V_{\rm O}$ dip quickly upon load current change. However, the controller regulates $V_{\rm O}$ according to the droop current i_{droop} , which is a real-time representation of $i_{\rm L}$; therefore it pulls $V_{\rm O}$ back to the level dictated by $i_{\rm L}$, causing the ring back problem. This phenomenon is not observed when the output capacitors.

Figure 19 shows two optional circuits for reduction of the ring back. R_{ip} and C_{ip} form an R-C branch in parallel with R_i, providing a lower impedance path than R_i at the beginning of i₀ change. R_{ip} and C_{ip} do not have any effect at steady state. Through proper selection of R_{ip} and C_{ip} values, i_{droop} can resemble i₀ rather than i_L, and V₀ will not ring back. The recommended value for R_{ip} is100 Ω C_{ip} should be determined through tuning the load transient response waveforms on an actual board. The recommended range for C_{ip} is 100pF~2000pF.

C_n is the capacitor used to match the inductor time constant. It usually takes the parallel of two (or more) capacitors to get the desired value. Figure 19 shows that two capacitors $C_{n,1}$ and $C_{n,2}$ are in parallel. Resistor R_n is an optional component to reduce the Vo ring back. At steady state, $C_{n.1}+C_{n.2}$ provides the desired C_n capacitance. At the beginning of io change, the effective capacitance is less because R_n increases the impedance of the C_{n.1} branch. As explained in Figure 16, Vo tends to dip when C_n is too small, and this effect will reduce the Vo ring back. This effect is more pronounced when Cn.1 is much larger than $C_{n,2}$. It is also more pronounced when R_n is bigger. However, the presence of R_n increases the ripple of the V_n signal if $C_{n,2}$ is too small. It is recommended to keep $\text{C}_{n.2}$ greater than 2200pF. R_n value usually is a few ohms. $\text{C}_{n.1},\,\text{C}_{n.2}$ and R_n values should be determined through tuning the load transient response waveforms on an actual board.

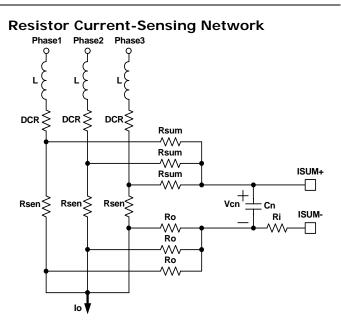


FIGURE 20. RESISTOR CURRENT-SENSING NETWORK

Figure 20 shows the resistor current-sensing network for a 3-phase solution. Each inductor has a series current-sensing resistor R_{sen} . R_{sum} and R_0 are connected to the R_{sen} pads to accurately capture the inductor current information. The R_{sum} and R_0 resistors are connected to capacitor C_n . R_{sum} and C_n form a a filter for noise attenuation. Equations 25 thru 27 give $V_{Cn}(s)$ expression:

$$V_{Cn}(s) = \frac{R_{sen}}{N} \times I_{o}(s) \times A_{Rsen}(s)$$
(EQ. 25)

$$A_{Rsen}(s) = \frac{1}{1 + \frac{s}{\omega_{sns}}}$$
(EQ. 26)

$$\omega_{\text{Rsen}} = \frac{1}{\frac{R_{\text{sum}}}{N} \times C_{\text{n}}}$$
(EQ. 27)

Transfer function $A_{Rsen}(s)$ always has unity gain at DC. Current-sensing resistor R_{sen} value will not have significant variation over temperature, so there is no need for the NTC network.

The recommended values are R_{sum} = 1k Ω and C_{n} = 5600pF.

Overcurrent Protection

Refer to Equation 1 and Figures 9, 14 and 20; resistor R_i sets the droop current I_{droop}. Table 3 shows the internal OCP threshold. It is recommended to design I_{droop} without using the R_{comp} resistor.

For example, the OCP threshold is 60μ A for 3-phase solution. We will design I_{droop} to be 38.8 μ A at full load, so the OCP trip level is 1.55 times of the full load current.

For inductor DCR sensing, Equation 28 gives the DC relationship of $V_{cn}(s)$ and $I_0(s)$.

Substitution of Equation 28 into Equation 1 gives Equation 29:

$$V_{Cn} = \left(\frac{R_{ntcnet}}{R_{ntcnet} + \frac{R_{sum}}{N}} \times \frac{DCR}{N}\right) \times I_{o}$$
(EQ. 28)

$$I_{droop} = \frac{2}{R_{i}} \times \frac{R_{ntcnet}}{R_{ntcnet} + \frac{R_{sum}}{N}} \times \frac{DCR}{N} \times I_{o}$$
(EQ. 29)

Therefore:

$$R_{i} = \frac{2R_{ntcnet} \times DCR \times I_{o}}{N \times \left(R_{ntcnet} + \frac{R_{sum}}{N}\right) \times I_{droop}}$$
(EQ. 30)

Substitution of Equation 20 and application of the OCP condition in Equation 30 gives Equation 31:

$$R_{i} = \frac{2 \times \frac{(R_{ntcs} + R_{ntc}) \times R_{p}}{R_{ntcs} + R_{ntc} + R_{p}} \times DCR \times I_{omax}}{N \times \left(\frac{(R_{ntcs} + R_{ntc}) \times R_{p}}{R_{ntcs} + R_{ntc} + R_{p}} + \frac{R_{sum}}{N}\right) \times I_{droopmax}}$$
(EQ. 31)

where I_{omax} is the full load current, $I_{droopmax}$ is the corresponding droop current. For example, given N = 3, R_{sum} = $3.65 k\Omega$, R_p = $11 k\Omega$, R_{ntcs} = $2.61 k\Omega$, R_{ntc} = $10 k\Omega$, DCR = $0.88 m\Omega$, I_{omax} = 51A and $I_{droopmax}$ = $40.9 \mu A$, Equation 31 gives R_i = 606Ω .

For resistor sensing, Equation 32 gives the DC relationship of $V_{CR}(s)$ and $I_{O}(s)$.

$$V_{Cn} = \frac{R_{sen}}{N} \times I_{o}$$
(EQ. 32)

Substitution of Equation 32 into Equation 1 gives Equation 33:

$$I_{droop} = \frac{2}{R_i} \times \frac{R_{sen}}{N} \times I_o$$
(EQ. 33)

Therefore:

$$R_{i} = \frac{2R_{sen} \times I_{o}}{N \times I_{droop}}$$
(EQ. 34)

Substitution of Equation 34 and application of the OCP condition in Equation 30 gives:

$$R_{i} = \frac{2R_{sen} \times I_{omax}}{N \times I_{droopmax}}$$
(EQ. 35)

where I_{omax} is the full load current, $I_{droopmax}$ is the corresponding droop current. For example, given N = 3, R_{sen} = 1m Ω , I_{omax} = 51A and $I_{droopmax}$ = 40.9 μ A, Equation 35 gives R_{i} = 831 Ω .

A resistor from COMP to GND can adjust the internal OCP threshold, providing another dimension of fine-tune flexibility. Table 3 shows the detail. It is recommended to scale I_{droop} such that the default OCP threshold gives approximately the desired OCP level, then use R_{comp} to fine tune the OCP level if necessary.

Load Line Slope

Refer to Figure 9.

For inductor DCR sensing, substitution of Equation 29 into Equation 2 gives the load line slope expression:

$$LL = \frac{V_{droop}}{I_o} = \frac{2R_{droop}}{R_i} \times \frac{R_{ntcnet}}{R_{ntcnet} + \frac{R_{sum}}{N}} \times \frac{DCR}{N}$$
(EQ. 36)

For resistor sensing, substitution of Equation 33 into Equation 2 gives the load line slope expression:

$$LL = \frac{V_{droop}}{I_o} = \frac{2R_{sen} \times R_{droop}}{N \times R_i}$$
(EQ. 37)

Substitution of Equation 30 and rewriting Equation 36, or substitution of Equation 34 and rewriting Equation 37 give the same result in Equation 38:

$$R_{droop} = \frac{I_o}{I_{droop}} \times LL$$
 (EQ. 38)

One can use the full load condition to calculate R_{droop} . For example, given $I_{omax} = 51A$, $I_{droopmax} = 40.9\mu A$ and LL = 1.9m Ω , Equation 38 gives $R_{droop} = 2.37 k \Omega$.

It is recommended to start with the R_{droop} value calculated by Equation 38, and fine tune it on the actual board to get accurate load line slope. One should record the output voltage readings at no load and at full load for load line slope calculation. Reading the output voltage at lighter load instead of full load will increase the measurement error.

Current Monitor

Refer to Equation 18 for the IMON pin current expression.

Refer to Figures 1 and 2, the IMON pin current flows through ${\sf R}_{imon}.$ The voltage across ${\sf R}_{imon}$ is expressed in Equation 39:

$$V_{Rimon} = 3 \times I_{droop} \times R_{imon}$$
(EQ. 39)

Rewriting Equation 38 gives Equation 40:

$$droop = \frac{I_0}{R_{droop}} \times LL$$
(EQ. 40)

Substitution of Equation 40 into Equation 39 gives Equation 41:

$$V_{Rimon} = \frac{3I_{o} \times LL}{R_{droop}} \times R_{imon}$$
(EQ. 41)

Rewriting Equation 41 and application of full load condition gives Equation 42:

$$R_{imon} = \frac{V_{Rimon} \times R_{droop}}{3I_o \times LL}$$
(EQ. 42)

For example, given LL = $1.9m\Omega$, R_{droop} = $2.37k\Omega$, V_{Rimon} = 963mV at I_{omax} = 51A, Equation 42 gives R_{imon} = $7.85k\Omega$.

A capacitor C_{imon} can be paralleled with R_{imon} to filter the IMON pin voltage. The $R_{imon}C_{imon}$ time constant is the user's choice. It is recommended to have a time constant long enough such that switching frequency ripples are removed.

Compensator

Figure 15 shows the desired load transient response waveforms. Figure 21 shows the equivalent circuit of a voltage regulator (VR) with the droop function. A VR is equivalent to a voltage source (= VID) and output impedance $Z_{out}(s)$. If $Z_{out}(s)$ is equal to the load line slope LL, i.e. constant output impedance, in the entire frequency range, V₀ will have square response when I₀ has a square change.

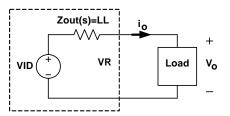


FIGURE 21. VOLTAGE REGULATOR EQUIVALENT CIRCUIT

Intersil provides a Microsoft Excel-based spreadsheet to help design the compensator and the current sensing network, so the VR achieves constant output impedance as a stable system. Figure 24 shows a screenshot of the spreadsheet.

A VR with active droop function is a dual-loop system consisting of a voltage loop and a droop loop which is a current loop. However, neither loop alone is sufficient to describe the entire system. The spreadsheet shows two loop gain transfer functions, T1(s) and T2(s), that describe the entire system. Figure 22 conceptually shows T1(s) measurement set-up and Figure 23 conceptually shows T2(s) measurement set-up. The VR senses the inductor current, multiplies it by a gain of the load line slope, then adds it on top of the sensed output voltage and feeds it to the compensator. T(1) is measured after the summing node, and T2(s) is measured in the voltage loop before the summing node. The spreadsheet gives both T1(s) and T2(s) plots. However, only T2(s) can be actually measured on an ISL62883 regulator.

T1(s) is the total loop gain of the voltage loop and the droop loop. It always has a higher crossover frequency than T2(s) and has more meaning of system stability.

T2(s) is the voltage loop gain with closed droop loop. It has more meaning of output voltage response.

Design the compensator to get stable T1(s) and T2(s) with sufficient phase margin, and output impedance equal or smaller than the load line slope.

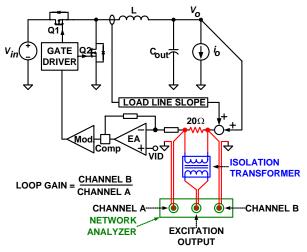


FIGURE 22. LOOP GAIN T1(s) MEASUREMENT SET-UP

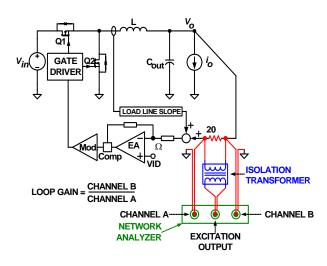


FIGURE 23. LOOP GAIN T2(s) MEASUREMENT SET-UP



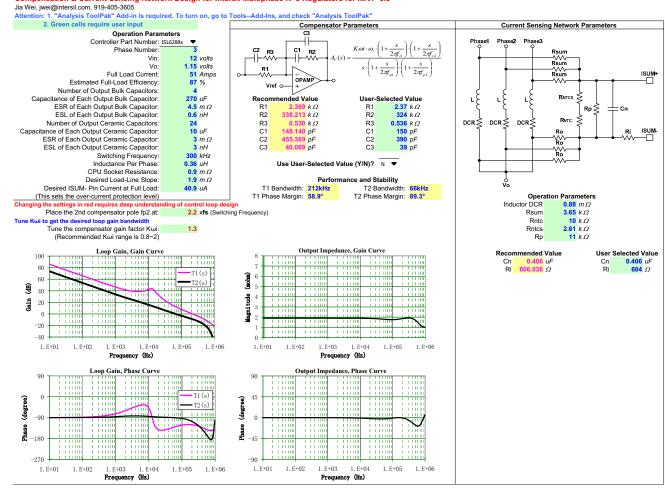


FIGURE 24. SCREENSHOT OF THE COMPENSATOR DESIGN SPREADSHEET

Compensation & Current Sensing Network Design for Intersil Multiphase R^3 Regulators for IMVP-6.5



25

Optional Slew Rate Compensation Circuit For 1-Tick VID Transition

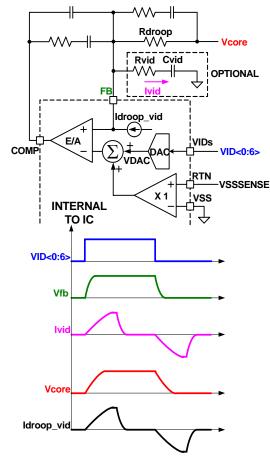


FIGURE 25. OPTIONAL SLEW RATE COMPENSATION CIRCUIT FOR1-TICK VID TRANSITION

During a large VID transition, the DAC steps through the VIDs at a controlled slew rate of 2.5 μ s per tick (12.5mV), controlling output voltage V_{core} slew rate at 5mV/ μ s.

Figure 25 shows the waveforms of 1-tick VID transition. During 1-tick VID transition, the DAC output changes at approximately 15mV/µs slew rate, but the DAC cannot step through multiple VIDs to control the slew rate. Instead, the control loop response speed determines V_{core} slew rate. Ideally, V_{core} will follow the FB pin voltage slew rate. However, the controller senses the inductor current increase during the up transition, as the I_{droop_vid} waveform shows, and will droop the output voltage V_{core} accordingly, making V_{core} slew rate slow. Similar behavior occurs during the down transition.

To control V_{core} slew rate during 1-tick VID transition, one can add the $R_{vid}\text{-}C_{vid}$ branch, whose current I_{vid} cancels $I_{droop_vid}.$

When V_{core} increases, the time domain expression of the induced I_{droop} change is expressed in Equation 43:

$$I_{droop}(t) = \frac{C_{out} \times LL}{R_{droop}} \times \frac{dV_{core}}{dt} \times \left(1 - e^{\frac{-t}{C_{out} \times LL}}\right)$$
(EQ. 43)

where Cout is the total output capacitance.

In the mean time, the R_{vid} - C_{vid} branch current I_{vid} time domain expression is shown in Equation 44:

$$I_{vid}(t) = C_{vid} \times \frac{dV_{fb}}{dt} \times \left(1 - e^{\frac{-t}{R_{vid} \times C_{vid}}}\right)$$
(EQ. 44)

It is desired to let $I_{vid}(t)$ cancel $I_{droop_vid}(t).$ So there are:

$$C_{vid} \times \frac{dV_{fb}}{dt} = \frac{C_{out} \times LL}{R_{droop}} \times \frac{dV_{core}}{dt}$$
(EQ. 45)

and:

$$R_{vid} \times C_{vid} = C_{out} \times LL$$
 (EQ. 46)

The result is expressed in Equation 47:

$$R_{vid} = R_{droop}$$
(EQ. 47)

and:

$$C_{vid} = \frac{C_{out} \times LL}{R_{droop}} \times \frac{\frac{dV_{core}}{dt}}{\frac{dV_{fb}}{dt}}$$
(EQ. 48)

For example: given LL = $1.9m\Omega$, $R_{droop} = 2.37k\Omega$, $C_{out} = 1320\mu$ F, $dV_{core}/dt = 5mV/us$ and $dV_{fb}/dt = 15mV/\mu$ s, Equation 47 gives $R_{vid} = 2.37k\Omega$ and Equation 48 gives $C_{vid} = 350$ pF.

It's recommended to select the calculated R_{vid} value and start with the calculated C_{vid} value and tweak it on the actual board to get the best performance.

During normal transient response, the FB pin voltage is held constant, therefore is virtual ground in small signal sense. The $R_{\text{Vid}}\text{-}C_{\text{Vid}}$ network is between the virtual ground and the real ground, and hence has no effect on transient response.

Voltage Regulator Thermal Throttling

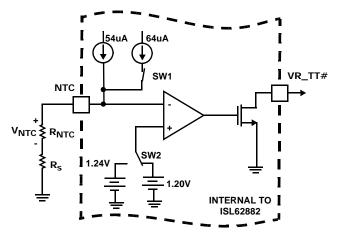


FIGURE 26. CIRCUITRY ASSOCIATED WITH THE THERMAL THROTTLING FEATURE OF THE ISL62882

Figure 26 shows the thermal throttling feature with hysteresis. An NTC network is connected between the NTC pin and GND. At low temperature, SW1 is on and SW2 connects to the 1.20V side. The total current flowing out of the NTC pin is 60µA. The voltage on NTC pin is higher than threshold voltage of 1.20V and the comparator output is low. VR_TT# is pulled up by the external resistor.

When temperature increases, the NTC thermistor resistance decreases so the NTC pin voltage drops. When the NTC pin voltage drops below 1.20V, the comparator changes polarity and turns SW1 off and throws SW2 to 1.24V. This pulls VR_TT# low and sends the signal to start thermal throttle. There is a 6µA current reduction on NTC pin and 40mV voltage increase on threshold voltage of the comparator in this state. The VR_TT# signal will be used to change the CPU operation and decrease the power consumption. When the temperature drops down, the NTC thermistor voltage will go up. If NTC voltage increases to above 1.24V, the comparator will flip back. The external resistance difference in these two conditions is expressed in Equation 49:

$$\frac{1.24V}{54\mu A} - \frac{1.20V}{60\mu A} = 2.96k \tag{EQ. 49}$$

One needs to properly select the NTC thermistor value such that the required temperature hysteresis correlates to 2.96k Ω resistance change. A regular resistor may need to be in series with the NTC thermistor to meet the threshold voltage values.

For example, given Panasonic NTC thermistor with B = 4700, the resistance will drop to 0.03322 of its nominal at +105°C, and drop to 0.03956 of its nominal at +100°C. If the required temperature hysteresis is +105°C to +100°C, the required resistance of NTC will be:

$$\frac{2.96 k\Omega}{(0.03956 - 0.03322)} = 467 k\Omega \tag{EQ. 50}$$

Therefore a larger value thermistor, such as 470k NTC should be used.

At +105°C, 470kΩ NTC resistance becomes $(0.03322 \times 470 \text{k}\Omega) = 15.6 \text{k}\Omega$. With 60µA on the NTC pin. the voltage is only $(15.6k\Omega \times 60\mu A) = 0.937V$. This value is much lower than the threshold voltage of 1.20V. Therefore, a regular resistor needs to be in series with the NTC. The required resistance can be calculated by Equation 51:

$$\frac{1.20V}{60\mu A} - 15.6k\Omega = 4.4k\Omega$$
 (EQ. 51)

4.42k is a standard resistor value. Therefore, the NTC branch should have a 470k NTC and 4.42k resistor in series. The part number for the NTC thermistor is ERTJOEV474J. It is a 0402 package. The NTC thermistor will be placed in the hot spot of the board.

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Current Balancing

Refer to Figures 1 and 2. The ISL62883 achieves current balancing through matching the ISEN pin voltages. Rs and C_s form filters to remove the switching ripple of the phase node voltages. It is recommended to use rather long R_SC_S time constant such that the ISEN voltages have minimal ripple and represent the DC current flowing through the inductors. Recommended values are $R_s = 10k\Omega$ and $C_s = 0.22\mu$ F.

Layout Guidelines

12

13

VSEN

RTN

decoupling.

Table 5 shows the layout considerations. The designators refer to the reference design shown in Figure 27.

PIN	NAME	LAYOUT CONSIDERATION
EP	GND	Create analog ground plane underneath the controller and the analog signal processing components. Don't let the power ground plane overlap with the analog ground plane. Avoid noisy planes/traces (e.g.: phase node) from crossing over/overlapping with the analog plane.
1	PGOOD	No special consideration
2	PSI#	No special consideration
3	RBIAS	Place the Rbias resistor (R16) in general proximity of the controller. Low impedance connection to the analog ground plane.
4	VR_TT#	No special consideration
5	NTC	The NTC thermistor (R9) needs to be placed close to the thermal source that is monitor to determine thermal throttling. Usually it's placed close to Phase-1 high- side MOSFET.
6	VW	Place the capacitor (C4) across VW and COMP in close proximity of the controller
7	COMP	Place the compensator components (C3,
8	FB	C6 R7, R11, R10 and C11) in general proximity of the controller.
9	ISEN3/FB2	A capacitor (C7) decouples it to VSUM Place it in general proximity of the controller. An optional capacitor is placed between this pin and COMP. (It's only used when the controller is configured 2-phase). Place it in general proximity of the controller.
10	ISEN2	A capacitor (C9) decouples it to VSUM Place it in general proximity of the controller.
11	ISEN1	A capacitor (C10) decouples it to VSUM Place it in general proximity of the controller.

Place the VSEN/RTN filter (C12, C13) in

close proximity of the controller for good

TABLE 5. LAYOUT CONSIDERATION

TABLE 5. LAYOUT CONSIDERATION (Continued)

PIN	NAME	YOUT CONSIDERATION (Continued)
14	ISUM-	Place the current sensing circuit in general
15	ISUM+	proximity of the controller. Place C82 very close to the controller. Place NTC thermistors R42 next to Phase- 1 inductor (L1) so it senses the inductor temperature correctly. Each phase of the power stage sends a pair of VSUM+ and VSUM- signals to the controller. Run these two signals traces in parallel fashion with decent width (>20mil). IMPORTANT: Sense the inductor current by routing the sensing circuit to the inductor pads. Route R63 and R71 to the Phase-1 side pad of inductor L1. Route R88 to the output side pad of inductor L1. Route R65 and R72 to the Phase-2 side pad of inductor L2. Route R90 to the output side pad of inductor L2. Route R67 and R73 to the Phase-3 side pad of inductor L3. Route R92 to the output side pad of inductor L3. If possible. Route the traces on a different layer from the inductor pad layer and use vias to connect the traces into the pads. from the inside of the inductor. The following drawings show the two preferred ways of routing current sensing traces. Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor Inductor
16	VDD	A capacitor (C16) decouples it to GND. Place it in close proximity of the controller.
17	VIN	A capacitor (C17) decouples it to GND. Place it in close proximity of the controller.
18	IMON	Place the filter capacitor (C21) close to the CPU.
19	BOOT1	Use decent wide trace (>30mil). Avoid any sensitive analog signal trace from crossing over or getting close.
20	UGATE1	Run these two traces in parallel fashion
21	PHASE1	with decent width (>30mil). Avoid any sensitive analog signal trace from crossing over or getting close. Recommend routing PHASE1 trace to the Phase-1 high-side MOSFET (Q2 and Q8) source pins instead of general Phase-1 node copper.

TABLE 5. LAYOUT CONSIDERATION (Continued)

PIN	NAME	LAYOUT CONSIDERATION			
22	VSSP1 LGATE1	Run these two traces in parallel fashion with decent width (>30mil). Avoid any sensitive analog signal trace from crossing over or getting close. Recommend routing VSSP1 to the Phase-1 low-side MOSFET (Q3 and Q9) source pins instead of general power ground plane for better performance.			
24	PWM3	No special consideration.			
25	VCCP	A capacitor (C22) decouples it to GND. Place it in close proximity of the controller.			
26	LGATE2	Run these two traces in parallel fashion			
27	VSSP2	with decent width (>30mil). Avoid any sensitive analog signal trace from crossing over or getting close. Recommend routing VSSP2 to the Phase-2 low-side MOSFET (Q5 and Q1) source pins instead of general power ground plane for better performance.			
28	PHASE2	Run these two traces in parallel fashion			
29	UGATE2	with decent width (>30mil). Avoid any sensitive analog signal trace from crossing over or getting close. Recommend routing PHASE2 trace to the Phase-2 high-side MOSFET (Q4 and Q10) source pins instead of general Phase-2 node copper.			
30	BOOT2	Use decent wide trace (>30mil). Avoid any sensitive analog signal trace from crossing over or getting close.			
31~3 7	VID0~6	No special consideration.			
38	VR_ON	No special consideration.			
39	DPRSLPVR	No special consideration.			
40	CLK_EN#	No special consideration.			
Other	Phase Node	Minimize phase node copper area. Don't let the phase node copper overlap with/getting close to other sensitive traces. Cut the power ground plane to avoid overlapping with phase node copper.			
Other		Minimize the loop consisting of input capacitor, high-side MOSFETs and low-side MOSFETs (e.g.: C27, C33, Q2, Q8, Q3 and Q9).			

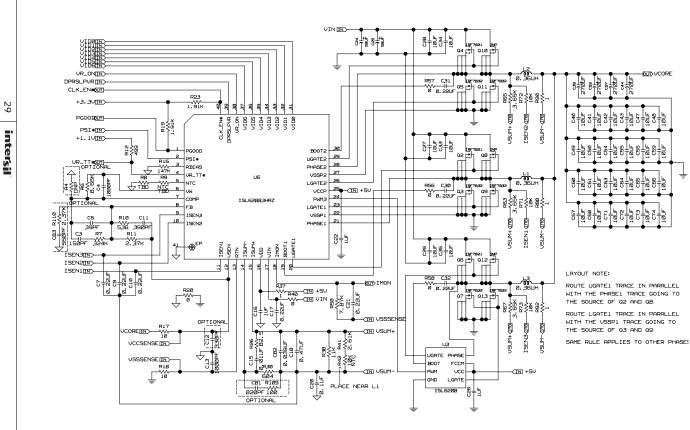


FIGURE 27. 3-PHASE REFERENCE DESIGN

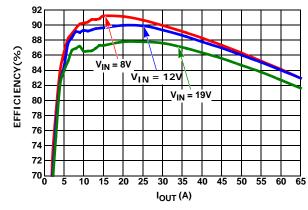
Reference Design Bill of Materials

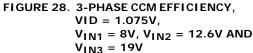
ΟΤΥ	REFERENCE	VALUE	DESCRIPTION	MANUFACTURER	PART NUMBER	PACKAGE
1	C11	390pF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00391-16V10	SM0603
1	C12	330pF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00331-16V10	SM0603
1	C13	1000pF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00102-16V10	SM0603
1	C15	0.01µF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00103-16V10	SM0603
3	C16, C22, C26	1µF	Multilayer Cap, 16V, 20%	GENERIC	H1045-00105-16V20	SM0603
1	C18	0.47µF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00474-16V10	SM0603
1	C20	0.1µF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00104-16V10	SM0603
8	C21, C7, C9, C10, C17, C30, C31, C32	0.22µF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00224-16V10	SM0603
2	C24, C25	56µF	Radial SP Series Cap, 25V, 20%	SANYO	25SP56M	CASE-CC
6	C27, C28, C29, C33, C34, C35	10µF	Multilayer Cap, 25V, 20%	GENERIC	H1065-00106-25V20	SM1206
1	C3	150pF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00151-16V10	SM0603
4	C39, C44, C52, C57	270µF	SPCAP, 2V, 4.5MOHM POLYMER CAP, 2.5V, 4.5mΩ	PANASONIC KEMET	EEFSX0D471E4 T520V477M2R5A(1)E4R5	
1	C4	1000pF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00102-16V10	SM0603
24	C40-C43, C47- C50, C53-C56, C59-C69, C78	10µF	Multilayer Cap, 6.3V, 20%	MURATA PANASONIC TDK	GRM21BR61C106KE15L ECJ2FB0J106K C2012X5R0J106K	SM0805
1	C6	39pF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00390-16V10	SM0603
1	C81	820pF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00821-16V10	SM0603
1	C82	0.039µF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00393-16V10	SM0603
1	C83	560pF	Multilayer Cap, 16V, 10%	GENERIC	H1045-00561-16V10	SM0603
3	L1, L2, L3	0.36µH	Inductor, Inductance 20%, DCR 5%	NEC-TOKIN PANASONIC	MPCH1040LR36 ETQP4LR36AFC	10mmx10m m
3	Q2, Q4, Q6		N-Channel Power MOSFET	IR	IRF7821	PWRPAKSO8
6	Q3, Q5, Q7, Q9, Q11, Q13		N-Channel Power MOSFET	IR	IRF7832	PWRPAKS08
3	Q8, Q10, Q12	DNP				
1	R10	536	Thick Film Chip Resistor, 1%	GENERIC	H2511-05360-1/16W1	SM0603
1	R109	100	Thick Film Chip Resistor, 1%	GENERIC	H2511-01000-1/16W1	SM0603
1	R11	2.37k	Thick Film Chip Resistor, 1%	GENERIC	H2511-02371-1/16W1	SM0603
1	R110	2.37k	Thick Film Chip Resistor, 1%	GENERIC	H2511-02371-1/16W1	SM0603
1	R12	499	Thick Film Chip Resistor, 1%	GENERIC	H2511-04990-1/16W1	SM0603
1	R16	147k	Thick Film Chip Resistor, 1%	GENERIC	H2511-01473-1/16W1	SM0603
2	R17, R18	10	Thick Film Chip Resistor, 1%	GENERIC	H2511-00100-1/16W1	SM0603
4	R19, R71, R72, R73	10k	Thick Film Chip Resistor, 1%	GENERIC	H2511-01002-1/16W1	SM0603
1	R23	1.91k	Thick Film Chip Resistor, 1%	GENERIC	H2511-01911-1/16W1	SM0603
1	R26	82.5	Thick Film Chip Resistor, 1%	GENERIC	H2511-082R5-1/16W1	SM0603
5	R20, R40, R56, R57, R58	0	Thick Film Chip Resistor, 1%	GENERIC	H2511-00R00-1/16W1	SM0603

Reference Design Bill of Materials (Continued)

QTY	REFERENCE	VALUE	DESCRIPTION	MANUFACTURER	PART NUMBER	PACKAGE
1	R30	604	Thick Film Chip Resistor, 1%	GENERIC	H2511-06040-1/16W1	SM0603
4	R37, R88, R90, R92	1	Thick Film Chip Resistor, 1%	GENERIC	H2511-01R00-1/16W1	SM0603
1	R38	11k	Thick Film Chip Resistor, 1%	GENERIC	H2511-01102-1/16W1	SM0603
1	R4	DNP				
1	R41	2.61k	Thick Film Chip Resistor, 1%	GENERIC	H2511-02611-1/16W1	SM0603
1	R42	10k NTC	Thermistor, 10k NTC	PANASONIC	ERT-J1VR103J	SM0603
1	R50	7.87k	Thick Film Chip Resistor, 1%	GENERIC	H2511-07871-1/16W1	SM0603
1	R6	8.66k	Thick Film Chip Resistor, 1%	GENERIC	H2511-08662-1/16W1	SM0603
3	R63, R65, R67	3.65k	Thick Film Chip Resistor, 1%	GENERIC	H2511-03651-1/16W1	SM0805
2	R8, R9	DNP				
1	R7	324k	Thick Film Chip Resistor, 1%	GENERIC	H2511-03243-1/16W1	SM0603
1	U3		Synchronous Rectified MOSFET Driver	INTERSIL	ISL6208CBZ	SOIC8_150_ 50
1	U6		IMVP-6.5 PWM Controller	INTERSIL	ISL62883HRTZ	QFN-40

Typical Performance





EFFICIENCY (%)

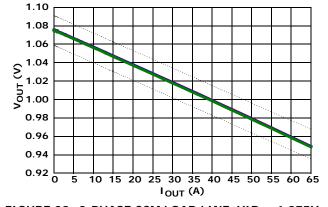
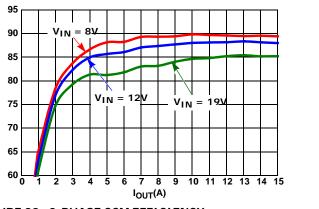


FIGURE 29. 3-PHASE CCM LOAD LINE, VID = 1.075V, $V_{IN1} = 8V, V_{IN2} = 12.6V \text{ AND}$ $V_{IN3} = 19V$



VID = 0.875V, $V_{IN1} = 8V, V_{IN2} = 12.6V AND$ $V_{IN3} = 19V$

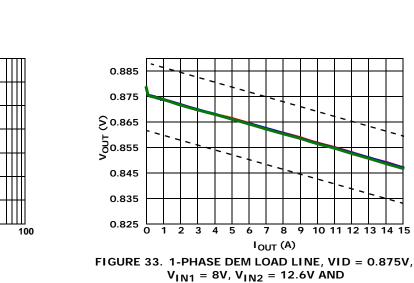
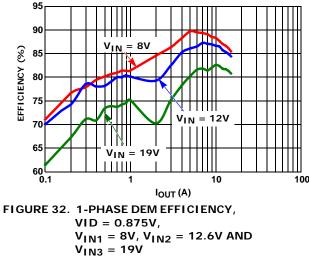


FIGURE 30. 2-PHASE CCM EFFICIENCY,



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0.885 0.875 €^{0.865} 0.855 0.845 0.835 0.825 8 9 10 11 12 13 14 15 3 4 5 6 7 2 I_{OUT} (A)

FIGURE 31. 2-PHASE CCM LOAD LINE, VID = 0.875V, $V_{IN1} = 8V, V_{IN2} = 12.6V \text{ AND}$ $V_{IN3} = 19V$



 $V_{IN3} = 19V$

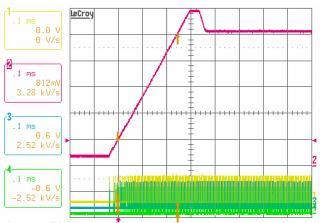


FIGURE 34. SOFT-START, $V_{IN} = 19V$, $I_O = OA$, VID = 0.95V, Ch1: PHASE1, Ch2: V_O , Ch3: PHASE2, Ch4: PHASE3

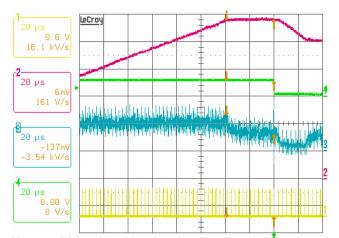
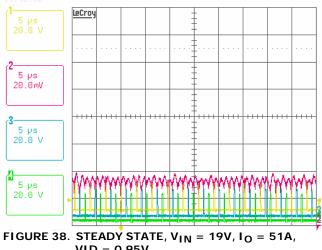


FIGURE 36. CLK_EN# DELAY, $V_{IN} = 19V$, $I_O = 2A$, VID = 1.5V, Ch1: PHASE1, Ch2: V_O , Ch3: IMON, Ch4: CLK_EN#



VID = 0.95V, Ch1: PHASE1, Ch2: V_O, Ch3: PHASE2, Ch4: PHASE3

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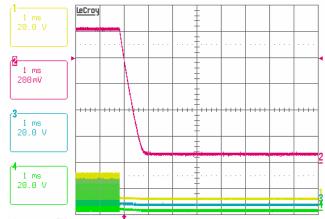


FIGURE 35. SHUT DOWN, $V_{IN} = 19V$, $I_O = 1A$, VID = 0.95V, Ch1: PHASE1, Ch2: V_O , Ch3: PHASE2, Ch4: PHASE3

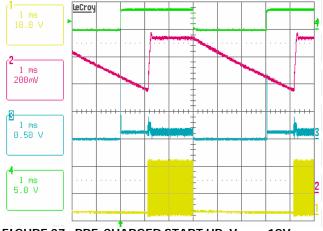
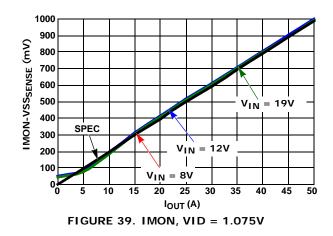
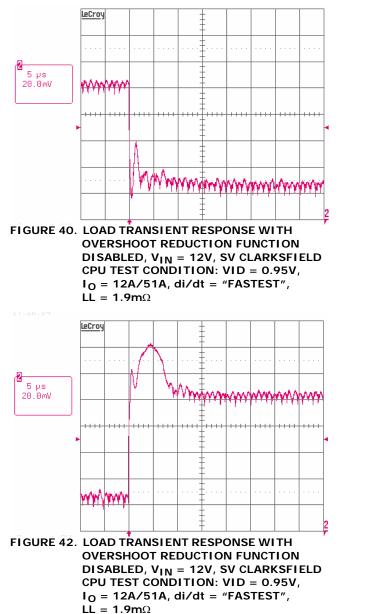


FIGURE 37. PRE-CHARGED START UP, $V_{IN} = 19V$, VID = 0.95V, $Ch1: PHASE1, Ch2: V_O, Ch3: IMON$, $Ch4: VR_ON$





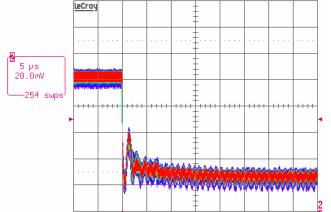


FIGURE 41. LOAD TRANSIENT RESPONSE WITH OVERSHOOT REDUCTION FUNCTION DISABLED, $V_{IN} = 12V$, SV CLARKSFIELD CPU TEST CONDITION: VID = 0.95V, $I_0 = 12A/51A$, di/dt = "FASTEST", LL = 1.9m Ω

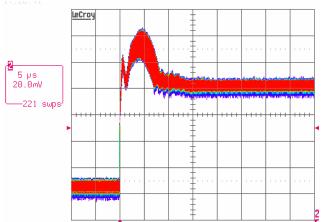
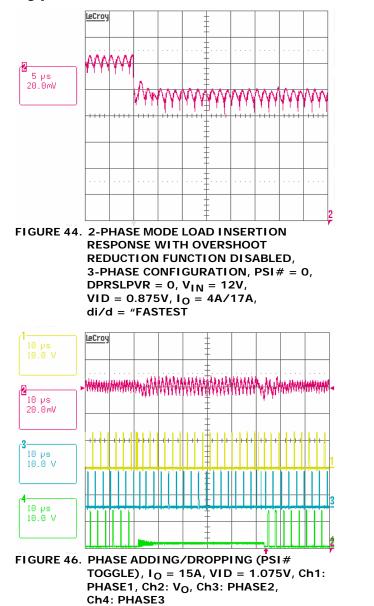


FIGURE 43. LOAD TRANSIENT RESPONSE WITH OVERSHOOT REDUCTION FUNCTION DISABLED, $V_{IN} = 12V$, SV CLARKSFIELD CPU TEST CONDITION: VID = 0.95V, $I_O = 12A/51A$, di/dt = "FASTEST", LL = 1.9m Ω



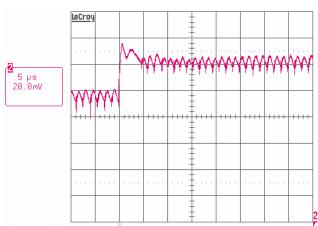


FIGURE 45. 2-PHASE MODE LOAD INSERTION RESPONSE WITH OVERSHOOT REDUCTION FUNCTION DISABLED, 3-PHASE CONFIGURATION, PSI# = 0, DPRSLPVR=0, V_{IN} = 12V, VID = 0.875V, I_O = 4A/17A, di/dt = "FASTEST"

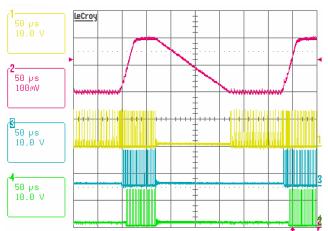


FIGURE 47. DEEPER SLEEP MODE ENTRY/EXIT, $I_O = 1.5A$, HFM VID = 1.075V, LFM VID = 0.875V, DEEPER SLEEP VID = 0.875V, Ch1: PHASE1, Ch2: V_O, Ch3: PHASE2, Ch4: PHASE3

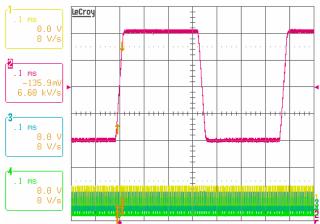


FIGURE 48. VID ON THE FLY, 1.075V/0.875V, 3-PHASE CONFIGURATION, PSI#=1, DPRSLPVR=0, Ch1: PHASE1, Ch2: V_O, Ch3: PHASE2, Ch4: PHASE3

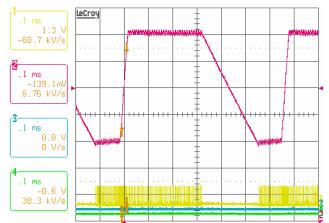


FIGURE 50. VID ON THE FLY, 1.075V/0.875V, 3-PHASE CONFIGURATION, PSI# = 0, DPRSLPVR = 1, Ch1: PHASE1, Ch2: V_O, Ch3: PHASE2, Ch4: PHASE3

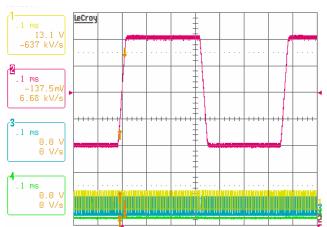


FIGURE 49. VID ON THE FLY, 1.075V/0.875V, 3-PHASE CONFIGURATION, PSI#=0, DPRSLPVR=0, Ch1: PHASE1, Ch2: V_O, Ch3: PHASE2, Ch4: PHASE3

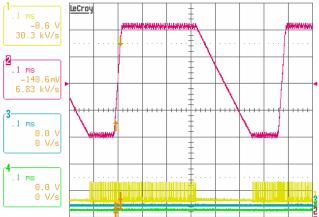


FIGURE 51. VID ON THE FLY, 1.075V/0.875V, 3-PHASE CONFIGURATION, PSI# = 1, DPRSLPVR = 1, Ch1: PHASE1, Ch2: V_O, Ch3: PHASE2, Ch4: PHASE3

LeCroy 2 µs 20.0mV 2 µs 10.0 V 2 µs 10.0 V

FIGURE 52. LOAD TRANSIENT RESPONSE WITH **OVERSHOOT REDUCTION FUNCTION** ENABLED, VIN = 12V, SV CLARKSFIELD CPU TEST CONDITION: VID = 0.95V, $I_0 = 12A/51A$, di/dt = "FASTEST", LL = $1.9m\Omega_i$ Ch1: LGATE1, Ch2: V_O, Ch3: LGATE2, Ch4: ISL6208 LGATE

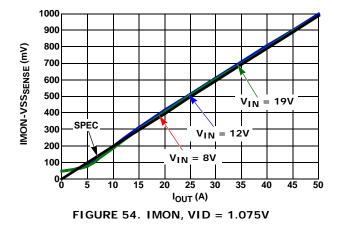
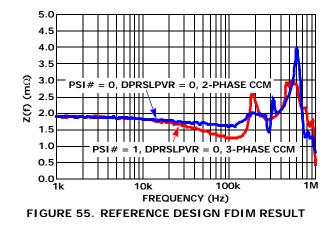




FIGURE 53. REFERENCE DESIGN LOOP GAIN T2(s) MEASUREMENT RESULT



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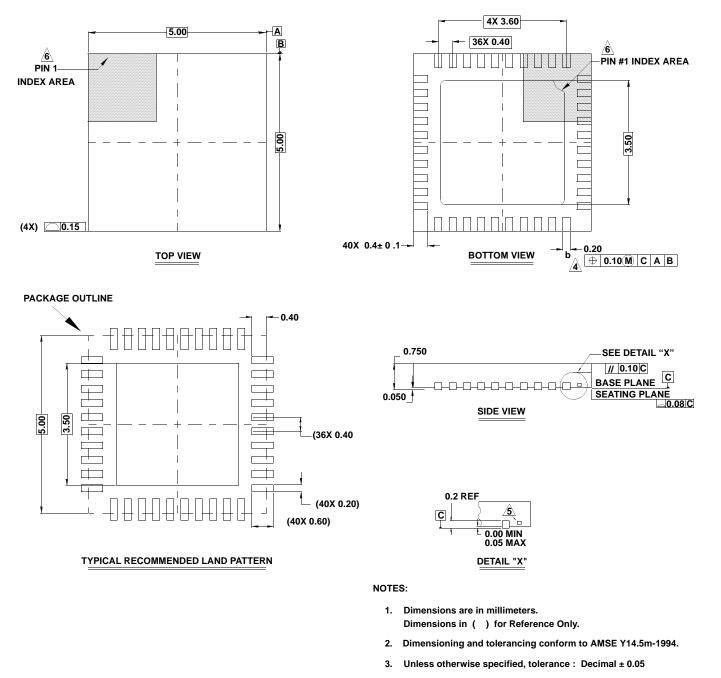
37 **inter_{sil}**

Typical Performance (Continued)

Package Outline Drawing

L40.5x5

40 LEAD THIN QUAD FLAT NO-LEAD PLASTIC PACKAGE Rev 1, 9/10

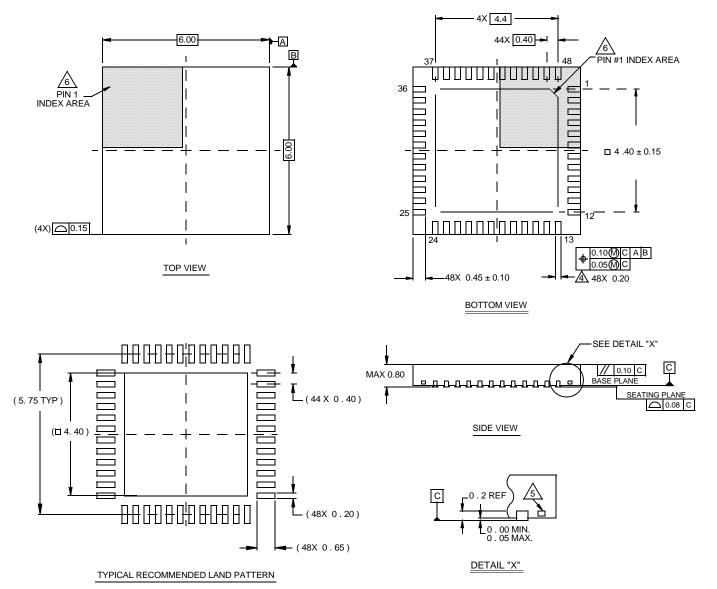


- 4. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.27mm from the terminal tip.
- 5. Tiebar shown (if present) is a non-functional feature.
- 6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 indentifier may be either a mold or mark feature.
- 7. JEDEC reference drawing: MO-220WHHE-1

Package Outline Drawing

L48.6x6

48 LEAD THIN QUAD FLAT NO-LEAD PLASTIC PACKAGE Rev 1, 4/07



NOTES:

- Dimensions are in millimeters.
 Dimensions in () for Reference Only.
- 2. Dimensioning and tolerancing conform to AMSE Y14.5m-1994.
- 3. Unless otherwise specified, tolerance : Decimal ± 0.05
- 4. Dimension b applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
- 5. Tiebar shown (if present) is a non-functional feature.
- 6. The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 indentifier may be either a mold or mark feature.